Electromechanical Relays Selection Guide

Latching

JAN



Non-Latching







RF

DC - 16 GHz

Established Reliability





Loopback







Environmental















Switching Solutions

Teledyne Relays has been the world's innovative leader in the manufacture of ultraminiature, hermetically sealed, electromechanical and solid-state switching products for more than 50 years. The company's comprehensive product line meets a wide range of requirements for defense and aerospace, industrial, commercial, medical and RF & wireless applications.

Business Focus

- MIL QPL & COTS Solid-State Relays
- MIL QPL & COTS Electromechanical Relays
- HiRel (Space) Electromechanical Relays
- RF & Microwave Relays & Coaxial Switches
- Industrial Solid-State Relays
- Switching Matrices

Markets

- Commercial & Military Aviation
- Defense & Aerospace
- Telecom/Communications (Wireless)
- Instrumentation & Test
- Industrial Power & Motion Control
- Medical Applications
- IC Semiconductor Test
- Oil & Gas

Product Assurance

Under an aggressive Total Quality Management (TQM) program, Teledyne Relays has embraced a "continuous improvement" culture. With recognized certifications such as Boeing D6-82479, MIL-STD-790, AS/EN/ JISQ9100:2009 (Rev C) and ISO 9001:2008 Teledyne Relays has become a primary supplier of switching solutions with the highest quality and reliability to industry leaders around the world.

Technical Service & Customer Support

Teledyne Relays provides easy access to technical service and customer support. Our websites make it easy to find technical information, buy products and even get e-mail responses within 24 hours. Switching solutions are only a mouse click away at www.teledynerelays.com or at teledyne-europe.com. Information about coax switches is available at www.teledynecoax.com.



Teledyne Relays offer superior signal integrity up to 40 Gbps. See the RF relays section in our website.

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See specific series for additional features and options

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GRF Option TO-5 Relays with straight butt pins for surfacemount applications * RF Relays Only



SGRF Option TO-5 Relays with Gull-Wing (J-Lead) pins for surface-mount applications * RF Relays Only



GRF Option Centigrid® Relays with straight butt pins for surface-mount applications * RF Relays Only



SGRF Option TO-5 Relays with Gull-Wing (J-Lead) pins for surface-mount applications * RF Relays Only



SRF Option Relays with Gull-Wing (J-Lead) pins for surface-mount applications * RF Relays Only



Spacer Pad Option Relays with polyester film pad to space between PCB and Relay Header See Appendix: Spacer Pad Options



Spreader Pad Option Relays with Diallyl Phthalate pad to spread pins See Appendix: Spreader Pad Options



/S Option Relays with 0.187" trimmed leads See Appendix: Part Numbering System



/Q, /R Option Relays with solder dipped leads. Pb/Sn (60/40) or RoHS solder available See Appendix: Part Numbering System

See specific series for additional features and options

Series GRF121 Electromechanical Relays

The ultraminiature GRF121 relay is designed to provide a practical surface-mount switching solution with RF performance and repeatability to 16GHz. The GRF121 improves on Teledyne Relays' heritage of miniature RF relays by incorporating a precision trasmission line structure in the internal construction of the contact system. GRF121 relays feature a unique ground shield to facilitate surface mounting and to extend the frequency range when compared to through-hole solutions.

- Broader bandwidth (DC 16GHz)
- Excellent Signal integrity up to 40Gbps
- Hermetically Sealed
- High Resistance to ESDMetal Enclosure for EMI shielding
- High Repeatability
- 3 Million Cycle Life

Relay Type		Typical RF Performance					
SPDT Magnetic-Latching	Part No.	Frequency (GHz)	VSWR	Isolation (dB)	Insertion Loss (dB) (max)		
Frequency Range							
RF121 = DC - 12 GHz	arters	DC - 4	1.3 : 1	55	0.25		
GRF121 = DC - 16 GHz		4 - 8	1.50 : 1	50	0.45		
Bit Rate	RF121						
RF121 = 20 Gbps		8 - 12	2.0 : 1	40	1.35		
GRF121 = 40 Gbps							
Mounting							
RF = Thru-hole	3	DC - 4	1.1 : 1	65	0.2		
GRF = Surface-Mount (Stub)	Real Conner	4.0	4.00.4	50	0.0		
Available Coil Voltages	121-5 GRE121	4 - 8	1.20 : 1	50	0.2		
5V: Coil Resistance (Ω) = 61 12V: Coil Resistance (Ω) = 500	GREE	8 - 12	1.35 : 1	40	0.5		
Tomporaturo		12 - 16	2.0 : 1	30	0.95		
Storage: -65°C to +125°C							
Operating: -55°C to +85°C							

GRF121 RF Characteristics







CONTACTS SHOWN IN POSITION RESULTING WHEN COIL A LAST ENERGIZED Schematics as viewed from terminals



GRF121 @ 28Gbps



 GRF121 @ 40Gbps

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Reference @ 16Gbps





LOOPBACK RELAYS

Series LB363/GLB363/SGLB363 Electromechanical Relays

The LoopBack Series relays combines to DPDT electromechanical relays in one package that includes an internal bypass path for Automated Test Equipment (ATE) applications. The LoopBack combines the technology of two Teledyne SGRF303 Series relays and eliminates the need for external PCB traces in loop back applications. This innovation results in superior signal integrity and RF performance while taking minimal board space. The internal structure of the LoopBack relays reduces the number of discontinuities and shortens the signal path during loop back testing, providing lower insertion loss and higher signal integrity performance than two SGRF303 Series relays. This LoopBack Relay is available with surface mount ground shield and J-lead configuration to provide improved high data rate and high frequency performance and ease of surface mount attachment.

• Excellent Signal integrity up to 16Gbps

- Hermetically Sealed
- High Resistance to ESD
- Metal Enclosure for EMI shielding
- High Repeatability
- Broader bandwidth
- Through-hole or surface-mount
- configurations
- 5 Million Cycle Life

Part Number		the second second	
	LB363	GLB363	SGLB363
Voltage (Vdc)	5,12	5,12	5,12
Coil Resistance (Ω)	56, 400	56, 400	56, 400
Frequency (GHz)	DC-6	DC-6	DC-6

	AC Bypass Path (Thru-CAP)		Through Path		AC Bypass Path (Thru-CAP)			Through Path				
	Single-Ended Bit Rate @ 12 Gbps		Single-Ended Bit Rate @ 12 Gbps		Single-Ended Bit Rate @ 16 Gbps		Single-Ended Bit Rate @ 16 Gbps					
	Eye Height (mV)	Eye Width (ps)	Jitter p-p (ps)	Eye Height (mV)	Eye Width (ps)	Jitter p-p (ps)	Eye Height (mV)	Eye Width (ps)	Jitter p-p (ps)	Eye Height (mV)	Eye Width (ps)	Jitter p-p (ps)
LB363	289	75	8.53	385	70.5	10.67	170	46.0	16.44	262	49.8	11.33
LB363	318	74.1	8.8	398	73.1	10.4	157	49.4	14.22	251	49.2	10.67
GLB363	329	74.2	7.2	395	73	11.2	173	48.3	12.67	288	47.9	11.56



(Contacts shown in De-Energized position) Figure 1: Single LoopBack Relay



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Two DPDT RelaysCapacitor Value000 = No capacitor010 = 10nF100 = 100nF220 = 220nFLB = Thru-holeGLB = Surface-MountGround Shield (Stub)SGLB = Surface-MountGround Shield(J-Lead)Temperature

Relay Type

```
Storage: -65°C to +125°C
Operating: -55°C to +85°C
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LOOPBACK RELAYS

Dual SGRF303 Loopback



Single LB363 Loopback



Dual SGRF303 Loopback



Single LB363 Loopback







Series RF300/RF303 Electromechanical Relays

The RF300 and RF303 TO-5 relays are designed to provide improved RF signal repeatability over the frequency range. The RF300 Series is offered with a standard or sensitive coil.

The GRF300 and GRF303 TO-5 relays feature a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact and pole-to-pole isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

The SGRF300 and SGRF303 TO-5 relays extend performance advantages over similar RF devices that simply offer formed leads for surface mounting.

- Excellent Signal integrity up to 18Gbps+
- Hermetically Sealed
- Metal Enclosure for EMI shielding
- High Repeatability
- Broader bandwidth
- Through-hole or surface-mount
- configurations • 10 Million Cycle Life

Relay Type Typical RF Performance DPDT Non-Latching Isolation (dB) Part No. Insertion Loss Frequency VSWR Pole to Pole (min) Across Contacts (min) (GHz) (dB) (max) Coil Type (max) 300 = Standard Coil DC-1 30 25 0.2 1.1 : 1 **RF300** 303 = Sensitive Coil **RF300D** 1-2 1.1:125 20 0.3 **Diode Option** 2-3 1.2:1 25 20 0.4 D = Internal diode for coil **RF303** transient suppression RF303D DD = Internal diode for coil 0.2 DC-1 1.1 : 1 40 30 **GRF300** transient suppression and GRF300D 30 0.2 1-3 1.1 : 1 40 polarity reversal protection Mounting 3-4 1.3 : 1 30 30 0.6 **GRF303** RF = Thru-hole GRF303D 4-6 1.6 : 1 25 25 1.0 GRF = Surface-Mount (Stub) DC-1 1.2 : 1 40 30 0.2 SGRF = Surface-Mount (J-Lead) SGRF300 SRF = Surface Mount (J-Lead) SGRF300D 1-3 1.2:1 40 30 0.4 Temperature 3-4 1.2:1 20 25 0.8 **SGRF303** Storage: -65°C to +125°C SGRF303D 4-6 1.8:1 10 20 1.0 Operating: -55°C to +85°C DC-1 1.1 : 1 25 25 0.5 SRF300 SRF300D 1-3 1.5 : 1 25 25 0.5 3-4 2.0:1 15 15 3.0 SRF303 SRF303D 4-6 2.5:1 10 10 4.0





Part No.		Nominal Coil*			
		Voltage (Vdc)	Resistance (Ω)		
	RF300	5	50		
RF 30 -12 0811	RF300D	12	390		
396	RF303	5	100		
	RF303D	12	850		

For RF300DD & RF303DD values, please see Datasheet. *RF, GRF, SGRF and SRF have equivalent Voltage Options and Coil Resistance.



Schematics as viewed from terminals

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20 Gbps



Series SI800/SI803 Electromechanical Relays

The miniature SI800/SI803 Series is designed for high-speed digital applications. They are capable of transmitting high-sped signals with data rates up to 20 Gbps. The SI800 series has a lower profile but higher coil operating power; whereas the SI803 Series has lower coil operating power but has a higher profile.

- Excellent Signal integrity up to 20Gbps
- High Repeatability
 Hermetically Sealed

 - High Resistance to ESD
 - Metal Enclosure for EMI shielding · Ground pin option to improve case

 - grounding 5 Million Cycle Life

Relay Type		Typical RF Performance						
DPDT Non-Latching	Part No.	Frequency	VSWR	Isolat	ion (dB)	Insertion Los		
Coil Type		(GHz)	(max)	Pole to Pole (min)	Across Contacts (min)	(dB) (max)		
SI800= Standard Coil SI803 = Sensitive Coil	SI800 SI803	DC-1	1.1 : 1	30	25	0.2		
Temperature		1-2	1.1 : 1	25	20	0.3		
Storage: -65°C to +125°C Operating: -55°C to +85°C		2-3	1.2 : 1	25	20	0.4		





Schematics as viewed from terminals





Data is the average from readings taken on all closed contacts.

16 Gbps



Eye Height	Eye Width	Jitter _{P-P}
296 mV	54.4 ps	8.22 ps

18 Gbps



Eye Height	Eye Width	Jitter _{P-P}
252 mV	46.1 ps	9.11 ps

20 Gbps



Eye Height	Eye Width	Jitter _{P-P}
191 mV	37 ps	10.22 ps

Series RF100/RF103 Electromechanical Relays

The RF100 and RF103 Centigrid® relays are designed to provide improved RF signal repeatability over the frequency range.

The GRF100 and GRF103 Centigrid® relays feature a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact and pole-to-pole isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

interface that results in improved high-frequency performance as well as parametric repeatability. The SGRF100 and SGRF103 Centigrid® relays extend performance advantages over similar RF devices that

simply offer formed leads for surface mounting.

- Excellent Signal integrity up to 18Gbps
 Hermetically Sealed
- High Resistance to ESD
- Metal Enclosure for EMI shielding
- High Repeatability
- Broader bandwidth
- Through-hole or surface-mount
- configurations

 10 Million Cycle Life

<u></u>	Relay Type	Part No.		Relay Type Typical RF Performance						
(b) 1(0) 8 2	DPDT Non-Latching			Frequency (GHz)	VSWR (max)	Isolation (dB)		Insertion		
	Coil Type					Pole to Pole (min)	Across Contacts (min)	Loss (dB) (max)		
	100 = Standard Coil	1 - L) E		DC-1	11.1	35	25	0.2		
	103 = Sensitive Coil	E ST	RF100					0.=		
100 RF100	RF100 Coil Voltage	RF100 Z-5		1-2	1.5 : 1	30	20	0.5		
103	5V: Coil Resistance (Ω) = 50 12V: Coil Resistance (Ω) = 390		RF103	2-3	1.6 : 1	30	20	0.6		
	RF103 Coil Voltage									
5	5V: Coil Resistance (Ω) = 100	0000	GRF100 GRF103	DC-1	1.1 : 1	45	30	0.2		
				1-3	1.2 : 1	40	25	0.3		
				3-4	1.3 : 1	35	25	0.6		
	GRF = Surface-Mount (Stub)			4-6	2.2 : 1	30	25	1.2		
	SGRF = Surface-Mount (J-Lead)			DC-1	1.2 : 1	35	30	0.2		
	Temperature	1	SGRF100	1_3	13.1	30	30	0.7		
	Storage: -65°C to +125°C			1-0	1.5 . 1	50	30	0.7		
	Operating: -55°C to +85°C	10 5	SGRE103	3-4	1.4 : 1	25	25	0.8		
			00.11100	4-6	1.8 : 1	25	25	1.0		

Series RF700/RF703 Electromechanical Relays

The ultraminiature RF700 and RF703 relays are designed to provide improved RF signal switching repeatability over the frequency range. These relays are engineered for use in RF attenuator, RF switch matrices, ATE and other applications that require dependable high frequency signal fidelity and performance. The Series RF700/RF703 relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay

Hermetically Sealed

- High Resistance to ESD
- Metal Enclosure for EMI shielding
- · High Repeatability
- Broader bandwidth
- Through-hole or surface-mount
- configurations

390

100

850

12 5

12

5 Million Cycle Life

	Relay Type				Typical RF Performance							
	DPDT Non-Latching	Part N	lo.	Frequency	VSWR	Isola	tion (dB)	Insertion				
	Coil Type	PE700		(ĠHz)	(max)	Pole to Pole (min)	Across Contacts (min)	Loss (dB) (max)				
700	700 = Standard Coil 703 = Sensitive Coil			DC-1	1.1 : 1	30	25	0.2				
703	Mounting	1 3 4	KI 700	1-2	1.1 : 1	25	20	0.3				
	RF = Thru-hole	7-17	RF703	2-3	1.2 : 1	25	20	0.4				
	SGRF = Surface-Mount (Stub)	11 11 11	11.700	3-4	1.2 : 1	20	20	0.55				
	Temperature			Noi	minal Coil							
	Storage: -65°C to +125°C Operating: -55°C to +85°C	Part No.		Voltage (Vdc)	Resi (stance Ω)						
			RF700	5		50						

RF703

@7 6 @

Series RF311/RF331 Electromechanical Relays

The RF311/RF331 relays are designed to provide improved RF signal repeatability over the frequency range. These relays are highly suitable for use in attenuator and other RF circuits.

The GRF311 offers monotonic insertion loss to 8GHz. This improvement in RF insertion loss over the

frequency range makes these relays highly suitable for use in attenuator and other RF circuits. The GRF311 features a unique ground shield that isolates and shields each lead to ensure excellent

contact-to-contact isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

· Excellent Signal integrity up to	10Gbp
 Hormotically Socied 	

- Hermetically Sealed
 High Resistance to ESD
- · Metal Enclosure for EMI shielding High Repeatability
- · Broader bandwidth
- Through-hole or surface-mount configurations
- 10 Million Cycle Life

Relay Type	Part No.		Typical RF Performance						
SPDT Non-Latching			Frequency	VSWR	Isolation Across	Insertion Loss			
Coil Type			(GHz)	(max)	(min)	(dB) (max)			
311 = Standard Coil	1920 - A		DC-2	1.3 : 1	25	0.2			
331 = Sensitive Coil	and the second		2-4	1.6 : 1	20	0.4			
RF311 Coil Voltage	5A	RF311			=0	0			
5V: Coil Resistance (Ω) = 50			4-6	1.6 : 1	20	0.6			
12V: Coil Resistance (Ω) = 390			6-8	1.6 : 1	15	0.8			
26V: Coil Resistance (Ω) = 2000				10.1	20	0.0			
RF331 Coil Voltage			DC-2	1.2 : 1	30	0.3			
5V: Coil Resistance (Ω) = 125	1 P		2-4	1.5 : 1	25	0.5			
12V: Coil Resistance (Ω) = 1025	1009	GRF311	4-6	15.1	25	07			
26V: Coil Resistance (Ω) = 4000	10								
Mounting			6-8	1.6 : 1	20	1.0			
RF = Thru-hole			DC-2	1.3 : 1	25	0.2			
GRF = Surface-Mount (Stub)	RF 331 05 161		2.4	16.1	20	0.4			
Temperature	43797	RF331	2-4	1.0.1	20	0.4			
Storage: -65°C to +125°C			4-6	1.6 : 1	20	0.6			
Operating: -55°C to +85°C			6-8	1.6 : 1	15	0.8			



Series RF341 Electromechanical Relays

The RF341 series relay is an ultraminiature, hermetically sealed, magnetic-latching relay featuring extremely low intercontact capacitance for exceptional RF performance well into the C band. Its low profile and small size make it ideal for applications where extreme packaging density and/or close PC board spacing are required. Due to its minimal mass, many relays may be used to configure replacements for bulkier switching solutions at substantial savings in weight. The RF341 design has been optimized by increasing the distance between the set/reset contacts. This design improvement makes these unique relays the perfect choice for use in RF attenuators, RF switching matrices and other RF applications requiring high isolation, low insertion loss and low VSWR.

- · Excellent Signal integrity up to 10Gbps
- Hermetically Sealed
- High Resistance to ESD
- · Metal Enclosure for EMI shielding
- · High Repeatability
- · Broader bandwidth
- · Through-hole or surface-mount configurations
- 10 Million Cycle Life

The GRF341 features a unique ground shield that isolates and shields each lead to ensure excellent contactto-contact isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

Relay Type			Typical RF Performance						
SPDT Magnetic-Latching	Part No.	Frequency	VSWR	Isolation Across	Insertion Loss				
Coil Type		(GHz)	(max)	(min)	(dB) (max)				
341 = Standard Coil		DC-2	1.2 : 1	30	0.5				
RF341 Coil Voltage	RF341-5 08111	2-4	1.2 : 1	25	0.8				
5V: Coil Resistance (Ω) = 61 12V: Coil Resistance (Ω) = 500 26V: Coil Resistance (Ω) = 2000	RF341	4-6	1.4 : 1	20	2.0				
Mounting		DC-2	12.1	35	0.3				
RF = Thru-hole GRF = Surface-Mount (Stub)	GRE341	2-4	1.3 : 1	30	0.7				
Temperature	a Par	4-6	1.4 : 1	25	1.5				
Storage: -65°C to +125°C									

Schematics as viewed from terminals

Series RF255/RF257 Electromechanical Relays

The Series RF255/257 The Series RF255 is an industry-standard, half-size, latching crystal can relay. These relays are highly suitable for high RF power applications (RF Power Handling) and other RF circuits. Teledyne Relays' Series RF255 offers: all welded construction, wire leads, gold-plated or solder-coated, matched seal for superior hermeticity, gold-plated contact assembly, modernized assembly process and advanced cleaning techniques.

- Excellent Signal integrity up to 10Gbps
- Hermetically Sealed
- · High Resistance to ESD
- Metal Enclosure for EMI shielding
- High Repeatability
- Broader bandwidth
- Through-hole or surface-mount configurations
- 1 Million Cycle Life
- **Relay Type Typical RF Performance** Insertion **DPDT Magnetic-Latching** Isolation (dB) Part No. Frequency VSWR Loss Pole to Pole Across Contacts (min) (min) Mounting (GHz) (max) (dB) (max) RF = Thru-hole DC-1 0.3 1.10:1 40 25 RF255 Coil Voltage 1-2 1.60:1 35 20 0.6 5V: Coil Resistance (Ω) = 45 **RF255** 6V: Coil Resistance (Ω) = 63 **RF257** 2-3 1.90:1 30 20 0.8 12V: Coil Resistance (Ω) = 254 26V: Coil Resistance (Ω) = 1000 Temperature Storage: -65°C to +125°C RF255 RF257 Operating: -55°C to +85°C



SCHEMATIC (Coil X Last Energized) (Bottom View)

Series GRF342 Electromechanical Relays

The Series GRF342 relay is a hermetically sealed, RF relay designed from inception for surface mount applications. This magnetic-latching relay features extremely low internal circuit losses for exceptional time and frequency domain response characteristics through and beyond the UHF spectrum and into the S band. The GRF342 features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact and pole-to-pole isolation. This ground shield provides an RF ground interface that results in improved high-frequency performance as well as parametric repeatability. The GRF342 extends performance advantages over similar RF devices that simply offer formed leads for surface mounting.

- Excellent Signal integrity up to 10Gbps
- Hermetically Sealed
- High Resistance to ESD
- Metal Enclosure for EMI shielding
- High Repeatability
- Broader bandwidth
- Through-hole or surface-mount
- configurations

SCHEMATIC

(Coil A Last Energized

• 10 Million Cycle Life

Relay Type		Typical RF Performance						
DPDT Magnetic-Latching	Part No.	Frequency	VSWR	Isola	tion (dB)	Insertion Loss		
Coil Type		(GHz)	(max)	Pole to Pole (min)	Across Contacts (min)	(dB) (max)		
342 = Standard Coil	ana an	DC-2	11.1	40	35	0.3		
RF342 Coil Voltage		002	1.1 . 1	40	00	0.0		
5V: Coil Resistance (Ω) = 61	GRF342	2-4	1.2 : 1	30	30	0.4		
12V: Coil Resistance (Ω) = 500	a (1)	4-6	14.1	25	25	0.8		
Mounting		10		20	20	0.0		
GRF = Surface-Mount (Stub)				COIL B				
Temperature								
Storage: -65°C to +125°C				-1	10			
Operating: -55°C to +85°C					\bigcirc ¹			
						342		

Schematics as viewed from terminals

Series RF180/GRF180 Electromechanical Relays

The Series RF180 relay is a hermetically sealed, magnetic-latching relay featuring extremely low intercontact capacitance for exceptional RF performance over the full UHF spectrum. Its low profile height and .100" (2.54 mm) grid spaced terminals make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The GRF180 features a unique ground shield that isolates and shields each lead to ensure excellent contactto-contact and pole-to-pole isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

- Excellent Signal integrity up to 10Gbps
 Hermetically Sealed
- High Resistance to ESD
- Metal Enclosure for EMI shielding
 High Repeatability
- Broader bandwidth
- Through-hole or surface-mount configurations
- 10 Million Cycle Life

Relay Type			Ту	pical RF P	erformance			
DPDT Magnetic-Latching	Part No. F		Frequency	VSWR	Isola	tion (dB)	Insertion Loss	
Coil Type			(GHz)	(max)	Pole to Pole (min)	Across Contacts (min)	(dB) (max)	
180 = Standard Coil				13.1	50	30	0.2	
RF180 Coil Voltage			00-2	1.0.1	50	50	0.2	
5V: Coil Resistance (Ω) = 61	Trett	RF180	2-4	1.3 : 1	45	30	0.3	
12V: Coil Resistance (Ω) = 500 26V: Coil Resistance (Ω) = 2000			4-6	2.0 : 1	30	25	1.5	
Mounting	-			12.1	50	35	0.2	
RF = Thru-hole	THERE GREAT	repared GRP 1.	00-2	1.2.1	50	55	0.2	
GRF = Surface-Mount (Stub)		GRF180	2-4	1.3 : 1	35	30	0.4	
	0000	Dp. qq		2.0.1	25	20	1 5	
Storage: -65°C to +125°C				2.0 1	25	30	1.5	
Operating: -55°C to +85°C								

9 ⊕ 10 ⊕ 1 8 ⊕ 0 2 7 ⊕ 0 3 6 ⊕ 0 4 s ⊕ 0 4 COLL A 180 SCHEMATIC (Coil B Last Energized)

Schematics as viewed from terminals

Series GRF172 Electromechanical Relays

The GRF172 Centigrid® relay is a hermetically sealed, armature relay for 2.5GHz RF applications. Its low profile height .330" (8.38 mm) and .100" (2.54 mm) grid spaced terminals make it an ideal choice where extreme packaging density and/or close PC board spacing are required. The GRF172 features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact and pole-to-pole isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability. The GRF172 extends performance advantages over similar RF devices that simply offer formed leads for surface mounting.

The Series GRF172D has an internal discrete silicon diode for coil suppression.

- Excellent Signal integrity up to 10Gbps
- Hermetically Sealed
- High Resistance to ESD
- Metal Enclosure for EMI shielding
- High Repeatability
- Broader bandwidth
- Through-hole or surface-mount configurations
- 5 Million Cycle Life

Relay Type	Part No. F			Т	ypical RF P	erformance	
DPDT Non-Latching			Frequency	VSWR	Isola	tion (dB)	Insertion Loss
Coil Type				(max)	Pole to Pole (min)	Across Contacts (min)	(dB) (max)
172 = Standard Coil		GRF172 GRF172D		11.1	45	30	0.2
RF172Coil Voltage	In a R				10	00	0.2
5V: Coil Resistance (Ω) = 64	0 4			1.2 : 1	40	25	0.3
12V: Coil Resistance (Ω) = 400	01.			1.2 : 1	40	25	0.3
Diede Option							
D = Internal diode for coil							
transient suppression							
Mounting							
GRF = Surface-Mount (Stub)							13
Temperature				ע		+ + +]
Storage: -65°C to +125°C			GRF172			GRF172D	
Operating: -55° C to $+85^{\circ}$ C							Schematics a

Series RF424/GRF424/SGRF424 Electromechanical Relays

The Series RF424/GRF424/SGRF424 relay is an ultraminiature, hermetically sealed, magnetic-latching relay featuring low intercontact capacitance for exceptional RF performance from DC-8 GHz. Its low profile and small size make it ideal for applications where extreme packaging density and/or close PC board spacing are required. The RF424 Series features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact and pole-to-pole isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

- Excellent Signal integrity up to 10Gbps
- Hermetically Sealed
- High Resistance to ESD
- Metal Enclosure for EMI shielding
- High Repeatability
- Broader bandwidth
- Through-hole or surface-mount configurations
- 10 Million Cycle Life

Relay Type				Ту	pical RF P	erformance	
4PST Magnetic-Latching	Pa	Frequency	VSWR	Isola	tion (dB)	Insertion Los	
Coil Type			(GHz)	(max)	Pole to Pole (min)	Across Contacts (min)	(dB) (max)
424 = Standard Coil			DC-2	1.10:1	50	30	0.2
RF424 Coil Voltage							
5V: Coil Resistance (Ω) = 61	1 mary	RF424	2-4	1.20:1	40	20	0.3
12V: Coil Resistance (Ω) = 500 26V: Coil Resistance (Ω) = 2000	7+7	RF424D	4-6	1.30:1	30	15	0.4
Mounting	<i>N</i> U L		6-8	1.60:1	25	15	0.6
RF = Thru-hole GRF = Surface-Mount (Stub) SGRF = Surface-Mount (J-Lead)	1000 A	GRF424					
Temperature	5	GRF424D	Contact Factory				
Storage: -65°C to +125°C	and the second s						
Operating: -55°C to +85°C							
	Ste .	SGRF424			Contact	Factory	

SGRF424D





(Coil B Last Energized) (Bottom View)

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SCHEMATIC (Coil B Last Energized) (Bottom View)

COIL A





Schematics as viewed from terminals For GRF424 and SGRF424 case to be grounded

Series RF310/RF313 Electromechanical Relays

The ultraminiature RF310 and RF313 relays are designed with an internal bypass (through path), when the coil is de-energized, to provide low insertion loss and VSWR through the bypass and simplicity of design for the user. Relays have improved RF insertion loss repeatability over the frequency range from DC to 3 GHz. Highly suitable for use in attenuator, linear amplifier and other RF circuits.

- N.C. bypass configuration
- Repeatable insertion loss
- Broad Bandwidth

- Metal Enclosure for EMI shielding
- Ground pin option to improve ground case RF grounding
- High isolation between control and signal path
- 10 Million Cycle Life

Relay Type			Nom	inal Coil		Typical RF Performance						
Normally Closed Bypass	Part No.		Voltage	/oltage Resistance F	Frequency	Frequency		Isolation (dB)		Insertion Loss (dB)		
Coil Type 310 = Standard Coil				(Ω)	(GHz)	N.O. (max)	Bypass (max)	N.O. (min)	Bypass (min)	N.O. (max)	Bypass (max)	
313 = Sensitive Coil	(SAC)		5	50	DC-1	1.2 : 1	1.3 : 1	35	25	0.2	0.3	
Mounting	RF310	RF310		300	1_2	12.1	13.1	25	25	03	0.4	
RF = Thru-hole		11 310	12	590	1-2	1.2.1	1.5 . 1	25	25	0.5	0.4	
Temperature	111				2-3	1.4 : 1	1.3 : 1	25	20	0.4	0.5	
Storage: -65°C to +125°C Operating: -55°C to +85°C	() () ()		5	100	DC-1	1.2 : 1	1.3 : 1	35	25	0.2	0.3	
	RF 315	RF313 RF313	12	850	1-2	1.2 : 1	1.3 : 1	25	25	0.3	0.4	
8 0 0 2) RE310	Ш				2-3	1.5 : 1	1.3 : 1	25	20	0.5	0.4	
(7 ⊚ 4 → 3) RF313												

Series RF320/RF323 Electromechanical Relays

The ultraminiature RF320 and RF323 relays are designed with an internal bypass (through path), when the coil is energized, to provide low insertion loss and VSWR through the bypass and simplicity of design for the user. The RF320 and RF323 relays have improved RF insertion loss repeatability over the frequency range from DC to 3 GHz. Highly suitable for use in attenuator, linear amplifier and other RF circuits.

- N.O. bypass configuration
- Repeatable insertion loss

Relay Type
Normally Open Bypass
Coil Type

Broad Bandwidth

320 = Standard Coil 323 = Sensitive Coil

<u>o</u>lo

- Metal Enclosure for EMI shielding
- · Ground pin option to improve ground case RF grounding
- High isolation between control and signal path
- 10 Million Cycle Life

	inal Coil		Typical RF Performance								
Part No.	Voltage	Voltage Resistance		VS	WR	Isolati	ion (dB)	Insertion Loss (dB)			
	(Vdc)	(Ω)	(GHz)	N.C. (max)	Bypass (max)	N.C. (min)	Bypass (min)	N.C. (max)	Bypass (max)		
RE320	5	50	DC-1	1.2 : 1	1.4 : 1	30	25	0.2	0.4		
RF320	12	390	1-2	1.2 : 1	1.4 : 1	30	20	0.3	0.4		
			2-3	1.4 : 1	1.4 : 1	25	20	0.4	0.6		
RF 323	5	100	DC-1	1.2 : 1	1.4 : 1	30	25	0.2	0.4		
RF323	12	850	1-2	1.2 : 1	1.4 : 1	30	20	0.3	0.4		
			2-3	1.4 : 1	1.4 : 1	25	20	0.4	0.5		

Schematics as viewed from terminals



Series A150 Electromechanical Relays

The Series A150 ultraminiature Attenuator Relays are designed for attenuating RF signals in 50-ohm systems over a frequency range from DC to 3 GHz. Their low profile and small grid spacing makes them ideal for use when packaging density is a prime consideration. The A150 relays eliminate the need for additional external resistors.

These single section, switchable attenuator relays have internal matched thin film attenuator pads in "L," "T" or "Pi" configurations, as applicable. Relays are available in fixed increments of 1, 2, 3, 4, 5, 6, 8, 10, 16 and 20 dB, which can be used singly or in combination to achieve the attenuation levels desired.

The GA150 features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

- Excellent phase linearity
 - Hermetically Sealed
- High Resistance to ESD
- Metal Enclosure for EMI shielding
- High Repeatability
- Broader bandwidth
- Through-hole or surface-mount configurations
- 10 Million Cycle Life

Nominal Coil Relay Type Typical RF Performance Insertion Loss VSWR **RF** Attenuator Part No. Voltage Resistance Frequency (dB)Coil Type (Vdc) **(**Ω**)** (GHz) Thru Path (Max.) Attenuated Path (Typ.) Тур Max. A150 = Standard Coil 5 50 DC-1 1.20:1 0.1 0.25 1.10:1 Mounting A = Thru-hole 12 390 1-2 130.1120.102 0.35 GA = Surface-Mount (Stub) A150 **Temperature** 15 610 2-3 1.40:1 1.25:1 0.3 0.55 Storage: -65°C to +125°C 26 1560 Operating: -55°C to +85°C 5 50 DC-1 1.20:1 1.20:1 0.1 0.25 ത്ത 12 390 1-2 1.20:1 1.20:1 0.2 0.35 150 GA150 610 2-3 1.20:1 1.30:1 0.3 0 45 15 26 1560 SCHEMATIC

Series A152 Electromechanical Relays

The Series A152 highly repeatable ultraminiature attenuator relays are designed for attenuating RF signals in 50-ohm systems over a frequency range from DC to 5 GHz. Their low profile and small grid spacing makes them ideal for use when packaging density is a prime consideration. The A152 relays eliminate the need for additional external resistors/attenuators.

These single section, switchable attenuator relays have an internal matched thin film attenuator pad in a "Pi" configuration. Relays are available in a fixed increment of 20 dB. (Other values available) The GA152 features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

- Hermetically Sealed
- High Resistance to ESD
- Metal Enclosure for EMI shielding
- · High Repeatability
- Broader bandwidth
- Through-hole or surface-mount configurations
- 10 Million Cycle Life

Relay Type		Nomii	nal Coil	Typical RF Performance					
RF Attenuator	Part No.	Voltage	Resistance	Frequency	VSI	NR	Insertion Loss (dB)		
Coil Type		(Vdc)	(Ω)	(GHz)	Attenuated Path (Typ.)	Thru Path (Max.)	Тур.	Max.	
Mounting		5	50	DC-1	1.20 : 1	1.10 : 1	0.1	0.25	
A = Thru-hole GA = Surface-Mount (Stub)	A152	12	390	1-2	1.30 : 1	1.20 : 1	0.2	0.35	
Temperature		15	610	2-3	1.40 : 1	1.25 : 1	0.3	0.55	
Storage: -65°C to +125°C Operating: -55°C to +85°C	111111	26	1560	3-5		See Da	tasheet		
3 5		5	50	DC-1	1.20 : 1	1.20 : 1	0.1	0.25	
	GA152	12	390	1-2	1.20 : 1	1.20 : 1	0.2	0.35	
	09091/2096	15	610	2-3	1.20 : 1	1.30 : 1	0.3	0.45	
		26	1560	3-5	1.40 : 1	1.70 : 1	0.4	0.55	

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COMMERCIAL RELAYS

Series 122C Electromechanical Relays

The 122C Centigrid® magnetic-latching relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" (2.54 mm) grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The basic operating function and internal structure are similar to Teledyne's TO-5, 422 relay series. The 122C is capable of meeting Teledyne Relays' T2R® requirements.

The Series 122C relay has internal silicon diodes for coil suppression, Zener diodes to protect the MOSFET gate inputs, and N-channel enhancement-mode MOSFET chips, which enable direct relay interfacing with most microprocessor and IC logic families (CMOS, TTL and MOS).

The 122C magnetic-latching relay is ideally suited for applications where coil operating power must be minimized. The relays can be operated with a short-duration pulse. After the contacts have transferred, no external coil power is required.

The magnetic-latching feature of the Series 122C relay provides a "memory" capability, since the relays will not reset upon removal of coil power.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- · High force/mass ratio for resistance to shock and vibration
- - Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
 - 10 Million Cycle Life

Relay Type						Nom	inal Coil		
DPDT Magnetic-Latch	ning	Part No		Voltago	Coil Cu		Operating	Latch and	Contact Load Rating
CMOS Feature	e			(Vdc)	Min	Max	Power (mW)	Reset Voltage	
Internal power MOSFE	ET				00.0	114.0	EOE		Desistives 14 (20) /de
driver and diode coil				5	82.2 41.6	57.0	505 206	3.5	Resistive: 1A/28VdC
suppression Vibration Shock		TH TELEDYNE VELO		9	27.4	37.0	288	6.8	Lamp: 100mA/28Vdc (320mm)
Vibration Sr	nock		122C	12	20.5	27.8	287	0.0	L_{0} and L_{0
30 g's 100 g's to 3000 Hz hal	s 6 msec, lf-sine			12	13.7	18.2	286	13.5	
Accoloration				26	11.4	15.2	351	18.0	
Acceleration									
50 g's					(° ~	10+ 1			
Temperature							PIN 4: GATE A		
Storage: -65°C to +125°C					7 0	0 3	PIN 5: – SUPPLY PIN 9: GATE B	122C	
Operating: -55°C to +85°C					6 0	4 5-	PIN 10: + SUPPLY		
					SCH	IEMATIC	·		

Series 172 Electromechanical Relays

The 172 Centigrid® relay is an ultraminiature, hermetically sealed, armature relay for commercial applications. Its low profile height .280" (7.11 mm) and .100" (2.54 mm) grid spaced terminals, which preclude the need for spreader pads, make it an ideal choice where extreme packaging density and/or close PC board spacing are required. The Series 172 relay has an internal discrete silicon diode for coil transient suppression. By virtue of its inherently low intercontact capacitance and contact circuit losses, the 172 relay is an excellent subminiature RF switch for frequencies well into the UHF spectrum. Applications include telecommunications, test instruments, mobile communications, attenuators, and automatic test equipment.

All welded construction

- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity · High force/mass ratio for resistance to
- shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities • 5 Million Cycle Life

Relay	/ Туре				Nomi	nal Coil			
DPDT Non-La	DPDT Non-Latching		Part No.		Resistance	P.U.V (Vdc) (max.)	Operating Power (mW)	Contact Load Rating	
Diode Options				3	39	2.25	235	Resistive: 1A/28Vdc	
D = Internal diode for coil		178-51	172	5	64	3.8	405	Inductive: 200mA/28Vdc (320mH)	
transient suppression		45832	172D	12	400	9.0	360	Lamp: 100mA/28Vdc	
Vibration	Shock			26	1600	18.0	440	Low Level: 10 to 50 uA/10 to 50 mV	
10 a's to 500 Hz	30 g's 6 msec,								
10 g s to 500 Hz	half-sine								
Tempe	erature				-		<u>_</u>	_	
Storage: -65°	'C to +125°C			07 0 1	©		7@ 0 0	,1	
Operating: -55°C to +85°C				P	چً 172 ع		⁶ @, , , , , , , , , , , , , , , , , , ,	² 172D	
				⁵ _ ⁴ 3	0			13	
Schematics as view	ved from terminals			L				P.U.V = Pick-Up Voltage	

Schematics as viewed from terminals

COMMERCIAL

COMMERCIAL RELAYS

Series 712 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, the Series 712 relays are some of the most versatile ultraminiature relays available because of their small size and low coil power dissipation.

The Series 712D relay has an internal discrete silicon diode for coil transient suppression. The hybrid Series 712TN relay has an internal silicon diode and transistor driver. The integrated packaging of the relay with its associated semiconductor devices greatly reduces PC board floor space requirements as well as component installation costs.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the 712 has proven to be excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the TO-5 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of Transmit-Receive switching.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay Type					Nom	inal Coil		
DPDT Non-Lat	tching	Part N	0.	Voltage	Resistance	P.U.V	Base Current	Contact Load Rating
Diode C	Options			(Vdc)	(Ω)	(Vdc) (max.)	(712 TN only)	
D = Internal diode for coil		and He		5	50	3.6	3.00	Resistive: 1A/28Vdc
transient suppression		712	12 712	6	98	4.2	2.04	Inductive: 200mA/28Vdc (320mH)
TN = Internal transistor driver		-12	712	9	220	6.5	1.36	Lamp: 100mA/28Vdc
and coil transient suppression			712D	12	390	8.4	1.03	Low Level: 10 to 50 uA/10 to 50 mV
diode			/121N	18	880	13.0	0.68	
Vibration	Shock	1111		26	1560	17.0	0.50	
	30 g's 6 msec,							
10 g s to 500 Hz	half-sine		八	_				
Tempe	erature		2000				Ţ	
Storage: -65°C to +125°C				4 ⊙3		70+4+403		
Operating: -55°C to +85°C				94		60-04		6004
		712			712D			712TN

Series 722 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, the 722 relay has become one of the most versatile ultraminiature relays available because of its small size and low coil power dissipation. The Series 722D relay has discrete silicon diodes for coil transient suppression. The Series 722 magnetic-latching relays are ideally suited for applications where coil power dissipation must be minimized. The relays can be operated with a short duration pulse and after the contacts have transferred, no external coil power is required. The magnetic-latching feature of the Series 722 provides a "memory" capability, since the relays will not reset upon removal of coil power.

All welded construction

 Unique uni-frame design providing high magnetic efficiency and mechanical rigidity

Schematics as viewed from terminals

- High force/mass ratio for resistance to shock
- and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
 10 Million Cycle Life

Relay	Туре				Nominal C	oil			
DPDT Magneti	ic-Latching	Part No).	Voltage (Vdc)	Resistance (Ω)	Set & Reset Voltage (Vdc)	Contact Load Rating		
Diode (Options	1977 Ba		5	61	3.5	Resistive: 1A/28Vdc		
D = Internal diode for coil		722-12		6	120	4.5	Inductive: 200mA/28Vdc (320mH)		
transient suppression		38 296	722	Q	280	6.8	Lamp: 100mA/28\/dc		
Vibration	Shock	T	722D		500	9.0	Low Level: 10 to 50 μ A/10 to 50 mV		
10 g's to 500 Hz	30 g's 6 msec,				1130	13.5			
half-sine		11110		26	2000	18.0			
Tempe	erature		C	OIL B			COIL B		
Storage: -65°	C to +125°C				7				
Operating: -5	5°C to +85°C								
					COIL A		COLLA 722D		
				SCHEMATIC (Coil A Last Energized) (Bottom View)			SCHEMATIC (coll A Last Energized) (Bottom View)		

COMMERCIAL RELAYS

Series 732 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, the Series 732 relay is one of the most versatile ultraminiature relays available because of their small size and low coil power dissipation. The sensitive 732 relay has a high resistance coil, thus requiring extremely low operating power (200 mW typical). The advantages of reduced heat dissipation and power supply demands are a plus.

The Series 732D relay has an internal discrete silicon diode for coil transient suppression. The hybrid Series 732TN relay has an internal silicon diode and transistor driver. The integrated packaging of the relay with its associated semiconductor devices greatly reduces PC board floor space requirements as well as component installation costs.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the 732 has proven to be excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the TO-5 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of Transmit-Receive switching.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay	Туре				Nom	inal Coil		
DPDT Non-Latching Coil		Part No.		Maltana	Registeres		Base Current	Contact Load Rating
Diode Options				(Vdc)	Resistance (Ω)	P.U.V (Vdc) (max.)	to Turn On	
D = Internal diode for coil								
transient suppi	transient suppression			5	100	3.5	1.50	Resistive: 1A/28Vdc
TN = Internal transistor driver		TELEDYNE	722	6	200	4.5	1.00	Inductive: 200mA/28Vdc (320mH)
and coil transient suppression		AULATE .	732	9	400	6.8	0.75	Lamp: 100mA/28Vdc
diode			732D	12	850	9.0	0.47	Low Level: 10 to 50 uA/10 to 50 mV
Vibration	Shock		/321N	18	1600	13.5	0.38	
	30 d's 6 msec	11.1.1.1		26	3300	18.0	0.24	
10 g's to 500 Hz	10 g's to 500 Hz half-sine							
Temperature								
Storage: -65°C to +125°C								



732





Schematics as viewed from terminals

Operating: -55°C to +85°C

COMMERCIAL SURFACE-MOUNT RELAYS

Series S114 & S134 Electromechanical Relays

The Series S114 Surface Mount Centigrid® Relay is an ultraminiature, hermetically sealed, armature relay. The low profile height .360" (9.14 mm) and .100" (2.54 mm) lead spacing make it ideal for applications where extreme packaging density and/or close PC board spacing are required. The specially formed leads are pre-tinned to make the relays ideal for most types of surface mount solder reflow processes.

The basic design and internal construction are identical to the Series 114 & 134 Centigrid® relays, and are capable of meeting Teledyne Relays' T2R® requirements.

The S114D and S114DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection.

The sensitive S134 surface mount Centigrid® Relay has a high resistance coil, thus requiring extremely low operating power (200 mW typical). The advantages of reduced heat dissipation and power supply demands are a plus.

- · All welded construction
- · Unique uni-frame design providing
- high magnetic efficiency and mechanical rigidity
- · High force/mass ratio for resistance to shock and vibration
- · Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

• 10 Million Cycle Life

Relay	Туре				Non	ninal Coil			
DPDT Non-Lat	tching	Part N	lo.	Voltage	Resistance	P.U.V	D.O.V	(Vdc)	Contact Load Rating
Coil	Туре			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
S114 = Standa	rd Coil			5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
S134 = Sensiti	ve Coil	21		6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
Diode (Options	- 3 3 14	S114	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
D = Internal diode for coil transient suppression DD = Internal diode for coil		2050	S114D	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
		1 TY		18	880	13.5	0.59	10.0	
				26	1560	18.0	0.89	13.0	
transient suppl	ression and			5	39	4.0	0.6	2.8	Resistive: 1A/28Vdc
polarity reversa	larity reversal protection			6	78	5.0	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
Vibration	Shock	TAN S	S114DD	9	220	7.8	0.8	5.3	Lamp: 100mA/28Vdc
30 d's to 3000	75 a's 6 msec.			12	390	10.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 mV
Hz	half-sine			18	880	14.5	1.1	10.0	
Accele	ration			26	1560	19.0	1.4	13.0	
				5	100	3.5	0.12	2.5	Resistive: 1A/28Vdc
50) g s	Det L		6	200	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
Tempe	erature	15 VV 82	S134	9	400	6.8	0.35	4.9	Lamp: 100mA/28Vdc
Storage: -65°	C to +125°C	Car Sta	S134D	12	800	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
Operating: -5	5°C to +85°C	T		18	1600	13.5	0.59	10.0	
				26	3200	18.0	0.89	13.0	
				5	64	3.7	0.7	2.6	Resistive: 1A/28Vdc
		Pro Contractor		6	125	4.8	0.8	3.0	Inductive: 200mA/28Vdc (320mH)
		1 1 1 PP	S134DD	9	400	8.0	0.9	4.5	Lamp: 100mA/28Vdc
		100500	S134DD	12	800	11.0	1.0	5.8	Low Level: 10 to 50 uA/10 to 50 mV
		Y AND		18	1600	14.5	1.1	9.0	
				26	3200	19.0	1.3	13.0	





S114D S134D



S114DD S134DD

COMMERCIAL SURFACE-MOUNT

Schematics as viewed from terminals

COMMERCIAL SURFACE-MOUNT RELAYS

Series S172 Electromechanical Relavs

The S172 surface mount Centigrid® relay is an ultraminiature, hermetically sealed, armature relay for commercial applications. Its low profile height .470" (11.94 mm) and .100" (2.54 mm) grid spaced terminals make it an ideal choice where extreme packaging density and/or close PC board spacing are required. The specially formed surface-mount leads are pre-tinned to make the relays ideal for all types of surface-mount solder reflow processes.

The basic design and internal structure are similar to Teledyne's DPDT 114 Centigrid® relay. (see page 16) The S172D relay has an internal discrete silicon diode for coil transient suppression.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity · High force/mass ratio for resistance to shock and vibration
- · Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 5 Million Cycle Life

Relay	/ Туре				Nomin	al Coil		
DPDT Non-Latching		Part No.		Voltage (Vdc)	Resistance (Ω)	P.U.V (Vdc) (max.)	Operating Power (mW)	Contact Load Rating
Diode (Diode Options		121257		64	3.8	405	Resistive: 1A/28Vdc
D = Internal diode for coil			S172	12	400	9.0	360	Inductive: 200mA/28Vdc (320mH)
transient suppression		2 0	S172D	26	1600	18.0	440	Lamp: 100mA/28Vdc
Vibration	Shock							Low Level: 10 to 50 uA/10 to 50 mV
10 a's to 500 Hz	30 g's 6 msec,							
10 g S 10 500 HZ	half-sine				2		ŗ_	
Temperature							700	
Storage: -65°C to +125°C							50 Q	
Operating: -55°C to +85°C					2		- +14	
				S172			S17	20

Series S422 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board surface mounting, its small size and low coil power dissipation make the S422 relay one of the most versatile ultraminiature relays available.

The Series S422D and S422DD utilize discrete diodes for coil suppression and polarity reversal protection. The Series S422 magnetic-latching relays are ideally suited for applications where power dissipation must be minimized. The relays can be operated with a short duration pulse. After the contacts have transferred, no external holding power is required.

The magnetic-latching feature of the Series S422 relays provide a "memory" capability, since the relays will not reset upon removal of coil power.

- · All welded construction
- · Unique uni-frame design providing high magnetic efficiency and mechanical rigidity · High force/mass ratio for resistance to
- shock and vibration Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay	у Туре				Nominal C	oil				
DPDT Magnet	tic-Latching	Part No).	Voltage (Vdc)	Resistance (Ω)	Set & Reset Voltage (Vdc)		Contact Load Rating		
Diode	Options			5	61	3.5		Resistive: 1A/28Vdc		
D = Internal di	iode for coil	32.2		6	120	4.5	Indu	ictive: 200mA/28Vdc (320m	ηH)	
transient supp	transient suppression		S422	9	280	6.8		Lamp: 100mA/28Vdc	<i>.</i>	
DD = Internal	diode for coil	36 S422D	12	500	9.0	Low	Low Level: 10 to 50 uA/10 to 50 mV			
transient supp	pression and	2775		18	1130	13.5				
polarity revers	olarity reversal protection			26	2000	18.0				
Vibration	Shock			5	48	4.5		Resistive: 1A/28Vdc		
	30 g's 6 msec,	C325-		6	97	5.5	Indu	ıctive: 200mA/28Vdc (320m	ηH)	
10 g's to 500 Hz	half-sine	54 36 S422DD	9	280	7.8		Lamp: 100mA/28Vdc	,		
Temp	erature		S422DD	12	500	10.0	Low	Low Level: 10 to 50 uA/10 to 50 mV		
Storage: -65	°C to +125°C	2775		18	1130	14.5				
Operating: -5	55°C to +85°C			26	2000	19.0				
				S422	COIL B		S422D		S422DD	

Schematics as viewed from terminals

SCHEMATIC (Coil A Last Energiz

COIL A



(Coil A Last Energize

1 1 COIL A

SCHEMATIC (Coil A Last Energized)

Series ER114 Electromechanical Relays

The Series ER114 Centigrid® relay is an ultraminiature, hermetically sealed, armature relay. Its low profile height .275" (7 mm) and 100" (2.54 mm) grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required. The basic design and internal construction are similar to the standard Teledyne DPDT TO-5 relay (e.g., Series FR412)

The Series ER114D and ER114DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the ER114 relay has proven to be an excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the ER114 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of Transmit-Receive switching.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity · High force/mass ratio for resistance to
- shock and vibration Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay Type					Non	ninal Coil			
DPDT Non-Lat	ching	Part No.		Voltage	Resistance	P.U.V	D.O.V	(Vdc)	Contact Load Rating
Diode C	Options			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
D = Internal dic	ode for coil			5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
transient suppr	ression	10 TELETINE		6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
DD = Internal d	liode for coil	EA	ER114	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
transient suppression and			ER114D	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
polarity reversa	al protection			18	880	13.5	0.59	10.0	
Vibration	Shock			26	1560	18.0	0.89	13.0	
30 g's	75 g's 6 msec,			5	39	4.0	0.6	2.8	Resistive: 1A/28Vdc
to 3000 Hz	half-sine	APTELEDING		6	78	5.0	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
Acceleration	Temperature	EA	FR114DD	9	220	7.8	0.8	5.3	Lamp: 100mA/28Vdc
Operating &			LICITADO	12	390	10.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 mV
50 g's	Storage:			18	880	14.5	1.1	10.0	
	–65°C to +125°C			26	1560	19.0	1.4	13.0	

Series ER116C Electromechanical Relays

The ER116C Centigrid® relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" (2.54 mm) grid spaced terminals, which preclude the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The Series ER116C utilizes an internal silicon diode for coil suppression, a Zener diode to protect the MOSFET gate input, and an N-channel enhancement mode MOSFET chip, which enables direct relay interfacing with most Microprocessor and IC logic families (CMOS, TTL and MOS).

- All welded construction
- Unique uni-frame design providing high
- magnetic efficiency and mechanical rigidity · High force/mass ratio for resistance to

- shock and vibration
- 10 Million Cycle Life

Relay	Туре				Nomina	l Coil		
DPDT Non-La	tching	Part No.	Voltage	tage (mA)		Operating	P.U.V	Contact Load Rating
CMOS	Feature		(Vdc)	Min.	Max.	Power (mW)	(Vdc) (max.)	
Internal power N	MOSFET		5	96.5	132.3	641	4.0	Resistive: 1A/28Vdc
driver, Zener die	ode gate protec-	1160	6	60.3	83.9	462	4.9	Inductive: 200mA/28Vdc (320mH)
tion, and diode coil suppression		-54	9	33.1	47.1	368	7.3	Lamp: 100mA/28Vdc
Vibration	Shock	ER116C	12	24.9	36.1	369	9.8	Low Level: 10 to 50 uA/10 to 50 m
30 g's	75 g's 6 msec,		18	16.1	24.1	368	14.6	
to 3000 Hz	half-sine	1	26	12.9	19.9	450	19.5	
Acceleration	Temperature							
Operating & 50 g's Storage:			_					9 ⁻ 10 + 1
	-65°C to +125°C	$\bigcirc 7 \bigcirc 1 \bigcirc 6 8 2$	7@			7000		
		P P	6@	$\bigcirc \qquad \bigcirc^2$	≠ ĝ	ିଡ୍	_@² ≠ ₿	PIN 1: + SUPPLY PIN 9: - SUPPLY

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ER114

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P.U.V = Pick-Up Voltage



Schematics as viewed from terminals

SHED RELIABILITY

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ER114D

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ER114DD

Series ER134 Electromechanical Relays

The ER134 sensitive Centigrid® relay retains the same features as the ER114 standard Centigrid® relay with only a minimal increase in profile height .375" (9.53 mm). Its .100" (2.54 mm) grid spaced terminals, which preclude the need for spreader pads, and its low profile make the ER134 relay ideal for applications where high packaging density is important. The Series ER134D and ER134DD have internal discrete silicon diodes for coil suppression and polarity reversal protection. The sensitive ER134 Centigrid® relay has a high resistance coil, thus requiring extremely low operating power (200 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay	туре			Nom	inal Coil			Contact Load Rating
DPDT Non-La	tching	Part No.	Voltage	Resistance	P.U.V	D.O.V	(Vdc)	
Diode (Options		(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
D = Internal die	ode for coil		5	100	3.5	0.12	2.5	Resistive: 1A/28Vdc
transient supp	ression	1 00134	6	200	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
DD = Internal of	diode for coil	ER134	9	400	6.8	0.35	4.9	Lamp: 100mA/28Vdc
transient supp	ression and	ER134D	12	800	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
polarity revers	al protection	DITI	18	1600	13.5	0.59	10.0	
Vibration	Shock	11111	26	3200	18.0	0.89	13.0	
30 q's	75 a's 6 msec.		5	64	3.7	0.7	2.6	Resistive: 1A/28Vdc
to 3000 Hz	half-sine	1 co134	6	125	4.8	0.8	3.0	Inductive: 200mA/28Vdc (320mH)
Acceleration	Temperature	5042400	9	400	8.0	0.9	4.5	Lamp: 100mA/28Vdc
Accoloration	remperature	ER134DD	12	800	11.0	1.0	5.8	Low Level: 10 to 50 uA/10 to 50 mV
	Operating &		18	1600	14.5	1.1	9.0	
50 g's	Storage:		26	3200	19.0	1.3	13.0	
	-65°C to +125°C	-						

Series ER136C Electromechanical Relays

The sensitive ER136C Centigrid® relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" (2.54 mm) grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

All welded construction

- All weided construction
 Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- 10 Million Cycle Life

The sensitive ER136C Centigrid® relay has a high resistance coil, thus requiring extremely low operating power (200 mW, typical). The advantages of reduced heat dissipation and power supply demands are a plus. The sensitive Series ER136C utilizes an internal silicon diode for coil suppression, a Zener diode to protect the MOSFET gate input, and an N-channel enhancement-mode MOSFET chip that enables direct relay interfacing with most microprocessor and IC logic families (CMOS, TTL and MOS).

Relay Type Nominal Coil Coil Current DPDT Non-Latching Part No. P.U.V **Contact Load Rating** Voltage Operating (mA)(Vdc) (max.) **CMOS** Feature (Vdc) Power (mW) Min Max. Internal power MOSFET 5 43.0 56.0 250 4.0 Resistive: 1A/28Vdc driver, Zener diode gate protec-6 27.0 Inductive: 200mA/28Vdc (320mH) 33.0 180 4.9 tion, and diode coil suppression 9 17.8 26.4 203 7.3 Lamp: 100mA/28Vdc ER136C Vibration Shock 12 11.3 177 180 98 Low Level: 10 to 50 uA/10 to 50 mV 30 g's 75 g's 6 msec, 18 8.4 13.8 203 14.6 to 3000 Hz half-sine 26 5.8 10.2 219 19.5 Acceleration Temperature Operating & Storage: 07 ٩ 10 50 g's 0 6 7@ @ [`] ⁷@ 0 2 စို -65°C to +125°C @² PIN 1: + SUPPLY PIN 9: - SUPPLY PIN 10: GATE ିଡ୍ ବ୍ଦୁ ____2² 18 5⊚ **|**@| + 4 ©⁵ 50 0 03 0: 30 é ER134 ER134D ER134DD ER136C

Schematics as viewed from terminals

ESTABLISHED RELIABILITY

P.U.V = Pick-Up Voltage

D.O.V = Drop-Out Voltage

Series ER411 & ER431 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed specifically for high-density PC board mounting, its small size and low coil power dissipation make the ER411 relay one of the most versatile ultraminiature relays available.

The Series ER411D and ER411DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid ER411T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

The sensitive ER431 relay has a high resistance coil, thus requiring extremely low operating power (150 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus.

The Series ER431D and ER431DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid ER431T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by minimizing the number of external components needed to drive the relay.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- · High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay	Туре				Nor	ninal Coil			
SPDT Non-Lat	ching	Part N	۱o.	Voltage	Resistance	PIIV	D.O.V	(Vdc)	Contact Load Rating
Coil ⁻	Гуре			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
ER411 = Stand	ard Coil	and the second s		5	63	3.7	0.15	2.4	Resistive: 1A/28Vdc
ER431 = Sensi	tive Coil	and the second		6	125	4.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
Diode C	options	The second second	ER411	9	280	6.8	0.35	4.2	Lamp: 100mA/28Vdc
D = Internal dic	de for coil	C. 1	ER411D	12	500	9.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
transient suppr	ession	I H H H		18	1130	13.5	0.58	8.4	
DD = Internal diode for coil				26	2000	18.0	0.89	10.4	
transient suppr	ession and	and the state		5	50	4.5	0.15	2.4	Resistive: 1A/28Vdc
polarity reversa	al protection	1 5 7 8 5 1		6	98	5.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
T = Internal transistor drive		10002	FR411DD	9	280	7.8	0.35	4.2	Lamp: 100mA/28Vdc
and coil transie	ent suppression		LIGHTOD	12	500	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
diode		1 P P P		18	1130	14.5	0.58	8.4	
Vibration	Shock	0.11		26	2000	19.0	0.89	10.4	
30 a's	75 g's 6 msec	A LE LA		5	63	3.9	0.15	2.4	Resistive: 1A/28Vdc
to 3000 Hz	half-sine	12 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2		6	125	5.2	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
Acceleration	Temperature		ER411T	9	280	7.8	0.35	4.2	Lamp: 100mA/28Vdc
Acceleration	Operating 8	M		12	500	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
50 a's	Storage:			18	1130	14.5	0.58	8.4	
00 9 5	-65°C to +125°C			26	2000	19.0	0.89	10.4	
		Called De		5	125	3.7	0.15	2.0	Resistive: 1A/28Vdc
		431	ER431	6	255	4.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
4		06461		9	630	6.8	0.35	4.2	Lamp: 100mA/28Vdc
	ER411		ER431D	12	1025	9.0	0.41	5.6	Low Level: 10 to 50 uA/10 to 50 mV
<u>3</u> 3 1 1 1 1 1 1 1 1 1 1	ER431			18	2300	13.5	0.58	8.4	
		1.8.1		26	4000	18.0	0.89	10.4	
		C-Stable		5	100	4.5	0.15	2.4	Resistive: 1A/28Vdc
4	7	431		6	200	5.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
	ER411D	06461	ER431DD	9	630	7.8	0.35	4.2	Lamp: 100mA/28Vdc
$3 \odot 10 2$	ER431D			12	1025	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
				18	2300	14.5	0.58	8.4	
		1.8.1		26	4000	19.0	0.89	10.4	
	•	Carling and		5	125	3.6	0.15	2.0	Resistive: 1A/28Vdc
	ER411DD	431 -5A		6	255	4.8	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
	ER431DD	06461	ER431T	9	630	7.8	0.35	4.2	Lamp: 100mA/28Vdc
,		83960		12	1025	10.0	0.41	5.6	Low Level: 10 to 50 uA/10 to 50 mV
				18	2300	14.5	0.58	8.4	
<u> </u>				26	4000	19.0	0.89	10.4	
10 to 1	•	Sohomotics of	winwood from	torminals					P.U.V = Pick-Up Voltage

Schematics as viewed from terminals

FR411T

ER431T

D.O.V = Drop-Out Voltage

Series ER412 & ER432 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed specifically for high-density PC board mounting, its small size and low coil power dissipation make the ER412 relay one of the most versatile ultraminiature relays available.

The Series ER412D and ER412DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid ER412T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

The sensitive ER432 relay has a high resistance coil, thus requiring extremely low operating power (200 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus.

The Series ER432D and ER432DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid ER432T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by minimizing the number of external components needed to drive the relay.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to
- shock and vibration
 - Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
 - 10 Million Cycle Life

Relay	Туре				Nom	inal Coil			
DPDT Non-Lat	tching	Part I	No.	Voltage	Resistance	P.U.V	D.O.V	(Vdc)	Contact Load Rating
Coil	Туре			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
ER412 = Stand	lard Coil	State of the		5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
ER432 = Sens	itive Coil	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
Diode C	Options	10072	ER412	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
D = Internal did	ode for coil		ER412D	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 uA
transient suppr	ression	16611		18	880	13.5	0.59	10.0	
DD = Internal of	liode for coil			26	1560	18.0	0.89	13.0	
transient suppression and		ALL AL		5	39	3.9	0.6	2.8	Resistive: 1A/28Vdc
polarity reversa	polarity reversal protection			6	78	5.2	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
T = Internal tra	nsistor drive		ER412DD	9	220	7.8	0.8	5.3	Lamp: 100mA/28Vdc
and coil transie	ent suppression			12	390	10.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 uA
diode		16661		18	880	14.5	1.1	10.0	
Vibration	Shock			20	1000	19.0	0.14	13.0	Desistive: 14/28//de
30 g's	75 g's 6 msec,	CR 05		5	00	3.5	0.14	2.3	Resistive: IA/20V0C
to 3000 Hz	half-sine			Q	220	4.J 6.8	0.10	J.2 4 9	l amp: 100mA/28Vdc (520mr)
Acceleration	Temperature		ER412T	12	390	9.0	0.33		Low Level: 10 to 50 μ A/10 to 50 mV
	Operating &			18	880	13.5	0.59	10.0	
50 g's	Storage:	1111		26	1560	18.0	0.89	13.0	
	–65°C to +125°C			5	100	3.5	0.14	2.5	Resistive: 1A/28Vdc
		43		6	200	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
		-5A 0305	ER432	9	400	6.8	0.35	4.9	Lamp: 100mA/28Vdc
	ER412	55200	ER432D	12	850	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
	ER432			18	1600	13.5	0.59	10.0	
60 04		// / / / /		26	3300	18.0	0.89	13.0	
• · · · ·		Con the		5	64	3.7	0.7	2.6	Resistive: 1A/28Vdc
		43		6	125	4.8	0.8	3.0	Inductive: 200mA/28Vdc (320mH)
	ER412D	0305	ER432DD	9	400	8.0	0.9	4.5	Lamp: 100mA/28Vdc
	ER432D	5520		12	850	11.0	1.0	5.8	Low Level: 10 to 50 uA/10 to 50 mV
0004				18	1600	14.5	1.1	9.0	
•	_	11 1 1 1		26	3300	19.0	1.3	13.0	
	a	and the second		5	100	3.6	0.14	2.5	Resistive: 1A/28Vdc
		-5A		6	200	4.8	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
	ER432DD	0305 55206	ER432T	9	400	7.8	0.35	4.9	Lamp: 100mA/28Vdc
				12	850	11.0	0.41	6.5 10.0	Low Level: 10 to 50 uA/10 to 50 mV
				26	3300	14.5	0.59	13.0	
+				20	5500	19.0	0.09	13.0	
	 ER412T	Schematics a	s viewed from	terminals					P.U.V = Pick-Up Voltage
70+4+403	FR432T								D.O.V = Drop-Out Voltage

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Series 255, 257 Electromechanical Relays

The Series 255 is an industry-standard, half-size, latching crystal can relay. It has a wide range of switching capabilities ranging from low level to 2 amps. The Series J255/255 latching relay configuration is double-pole double-throw (DPDT), so the relay offers excellent switching density and versatility. Half-Size Crystal Can Features:

- Low level to 2 amps
- Wide range of switching capabilities
- Smallest relay package capable of switching 2 amps
- Modernized assembly process
- Lead-free (gold-plated wire lead only)

- All welded construction
- Wire leads, gold-plated or solder-coated
- Matched seal for superior hermeticity
- Gold-plated contact assembly
- Modernized assembly process
- Advanced cleaning techniques
- 1 Million Cycle Life

Relay Type			Nomi	nal Coil		
DPDT Magnetic-Latching	Part No.	Voltage	Resistance (Ω)	Set & Res	et Voltage	Contact Load Rating
Vibration		(Vdc)		Min.	Max.	
30G, 10-2500 Hz		5	45	1.0	3.8	Resistive: 2A/28Vdc
(Sinusoidal)	2	55 ₆	63	13	4.5	Inductive: 0.754/28//dc (320mH)
Shock	2	56	03	1.5	4.5	Inductive: 0.75A/26vdc (520IIIFI)
100G, 6 msec half-sine	2	57 ¹²	254	2.6	9.0	Intermediate Current: 0.1A/28Vdc
(Specified Pulse)	2	58 26	1000	5.2	18.0	Lamp: 0.16A/28Vdc
Temperature						Low Level: 10 to 50 uA/10 to 50 mV
Operating & Storage:		25	7		255	
-65°C to +125°C		B3 A2	AI	B3 A2	AI	



Series ER421 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, its small size and low coil power dissipation make the ER421 relay one of the most versatile ultraminiature relays available.

The Series ER421D and ER421DD utilize discrete silicon diodes for coil suppression and polarity reversal protection.

The Series ER421 magnetic-latching relays are ideally suited for applications where coil power dissipation must be minimized. The relays can be operated with a short duration pulse. After the contacts have transferred, no external holding power is required. The magnetic-latching feature of the Series ER421 provides a "memory" capability, since the relays will not reset upon removal of coil power.

All welded construction

- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
 High force/mass ratio for resistance to
- shock and vibration • Precious metal alloy contact material with
- gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay	Туре		Nominal Coil			oil			
SPDT Magneti	c-Latching	Part I	No.	Voltage (Vdc)	Resistance (Ω)	Set & Reset Voltage (Vdc)	Contact Load Rating		
Diode C	options			5	61	3.5	Resistive: 1A/28Vdc		
D = Internal die	ode for coil	No.		6	120	4.5	Inductive: 200mA/28Vdc (320mH)		
transient suppr	ression	- 22		9	280	6.8	Lamp: 100mA/28Vdc		
DD = Internal o	liode for coil	7 8	ER421	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV		
transient suppr	ession and	791		18	1130	13.5			
polarity reversa	al protection			26	2000	18.0			
Vibration	Shock		ER421D	5	61	3.7	Resistive: 1A/28Vdc		
30 g's	100 g's 6 msec,	No. A.		6	120	4.5	Inductive: 200mA/28Vdc (320mH)		
to 3000 Hz	half-sine	- 22		9	280	6.8	Lamp: 100mA/28Vdc		
Acceleration	Temperature	A P		12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV		
	Operating &	A PARA		18	1130	13.5			
50 g's	Storage:			26	2000	18.0			
	–65°C to +125°C			5	48	4.5	Resistive: 1A/28Vdc		
*See Schematics on Page 21		No. C.		6	97	5.5	Inductive: 200mA/28Vdc (320mH)		
		a ??.		9	280	7.8	Lamp: 100mA/28Vdc		
		1	ER4210D	12	500	10.0	Low Level: 10 to 50 uA/10 to 50 mV		
		The second		18	1130	14.5			
				26	2000	19.0			

Series ER420 & ER422 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, its small size and low coil power dissipation make the ER420 & ER422 relays some of the most versatile ultraminiature relays available.

The Series ER420D/ER422D and ER420DD/ER422DD utilize discrete silicon diodes for coil suppression and polarity reversal protection.

The Series ER420/ER422 magnetic-latching relays are ideally suited for applications where coil power dissipation must be minimized. The relays can be operated with a short duration pulse. After the contacts have transferred, no external holding power is required. The magnetic-latching feature of the Series ER420/ER422 relays provide a "memory" capability, since the relays will not reset upon removal of coil power.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
 High force/mass ratio for resistance to
- High force/mass rati shock and vibration
 - Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
 - 10 Million Cycle Life

Relay	Туре	Part No.			Nominal C	oil	
DPDT Magneti	c-Latching			Voltage (Vdc)	Resistance	Set & Reset	Contact Load Rating
Grounding	g Options			5	61	3.5	Resistive: 14/28//dc
420 = Commor	ו	1-2-10 S	ED420	6	120	5.5	Inductive: 200mA/28)/dc (220mH)
422 = Individua	al	and the second s	ER420	0	120	4.5	
Diada			ER422	9	280	6.8	Lamp: 100mA/28Vdc
Diode C	options		ER420D	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
D = Internal dic	ode for coil	ITTI	ER422D	18	1130	13.5	
transient suppr	ression	111 .		26	2000	18.0	
DD = Internal o	liode for coil	and a second		5	48	4.5	Resistive: 1A/28Vdc
transient suppr	ession and	1-5- 9.5.		6	97	5.5	Inductive: 200mA/28Vdc (320mH)
polarity reversa	al protection	The second	ER420DD	9	280	7.8	Lamp: 100mA/28Vdc
Vibration	Shock	L	ER422DD	12	500	10.0	Low Level: 10 to 50 uA/10 to 50 mV
30 g's	100 g's 6 msec,	ागगा		18	1130	14.5	
to 3000 Hz	half-sine			26	2000	19.0	
Acceleration	Temperature						



Operating &

Storage:

-65°C to +125°C

50 g's

ER420



ER420D



ER420DD





COIL A





Schematics Shown with Coil A Last Energized Schematics as viewed from terminals

Series J114 Electromechanical Relays

The Series J114 Centigrid® relay is an ultraminiature, hermetically sealed, armature relay. Its low profile height .275" (7 mm) and .100" (2.54 mm) grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required. The basic design and internal construction are similar to the standard Teledyne DPDT TO-5 relay (e.g., Series J412).

The Series J114D and J114DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the J114 relay has proven to be an excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the J114 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of Transmit-Receive switching.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
 High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay	Туре	Part No.		Nominal Coil					
DPDT Non-Lat	ching			Voltage	Resistance	P.U.V	D.O.V (Vdc)		Contact Load Rating
Diode C	Options			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
D = Internal did	ode for coil			5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
transient suppr	ression	APTRI COURSE	J114	6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
DD = Internal c	liode for coil	(M39016/17	(M39016/17)	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
transient suppr	ession and		.I114D	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
polarity reversa	polarity reversal protection		(M39016/18)	18	880	13.5	0.59	10.0	
Vibration	Shock			26	1560	18.0	0.89	13.0	
30 g's	75 g's 6 msec,			5	39	4.0	0.6	2.8	Resistive: 1A/28Vdc
to 3000 Hz	half-sine	APTELEDINE		6	78	5.0	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
Acceleration	Temperature	U.	J114DD (M39016/18)	9	220	7.8	0.8	5.3	Lamp: 100mA/28Vdc
	Operating &			12	390	10.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 mV
50 q's	Storage:			18	880	14.5	1.1	10.0	
5	-65°C to +125°C			26	1560	19.0	1.4	13.0	

Series J116C Electromechanical Relays

The J116C Centigrid® relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" (2.54 mm) grid spaced terminals, which preclude the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

All welded construction

- Unique uni-frame design providing high
- magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- 10 Million Cycle Life

The Series J116C utilizes an internal silicon diode for coil suppression, a Zener diode to protect the MOSFET gate input, and an N-channel enhancement mode MOSFET chip, which enables direct relay interfacing with most Microprocessor and IC logic families (CMOS, TTL and MOS).

Nominal Coil Relay Type Coil Current DPDT Non-Latching Part No. P.U.V **Contact Load Rating** Voltage Operating (mA) (Vdc) **CMOS Feature** (Vdc) Power (mW) (max. Мах Internal power MOSFET 96.5 132.3 5 641 40 Resistive: 1A/28Vdc driver, Zener diode gate protec--54 6 60.3 83.9 462 4.9 Inductive: 200mA/28Vdc (320mH) tion, and diode coil suppression 9 33.1 47.1 368 7.3 Lamp: 100mA/28Vdc J116C Vibration Shock (M28776/6) 12 24.9 36.1 369 9.8 Low Level: 10 to 50 uA/10 to 50 mV 30 q's 75 q's 6 msec, 16.1 368 18 24.1 14.6 to 3000 Hz half-sine 26 12.9 19.9 450 19.5 Acceleration Temperature Operating & Storage: 50 g's 07 ٩ 10 0 . () ″⊚ 0 © . 0 -65°C to +125°C 2 O é ି୍ତ୍ ୕ଵୄ φ^2 PIN 1: + SUPPLY PIN 9: – SUPPLY PIN 10: GATE 50 0 ³0 ©⁵ 0: 5⊚_<mark>_</mark>@_ **⊙**3 ō P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage J114DD J116C J114 J114D

Schematics as viewed from terminals

Series J134 Electromechanical Relays

The J134 sensitive Centigrid® relay retains the same features as the J114 standard Centigrid® relay with only a minimal increase in profile height .375" (9.53 mm). Its .100" (2.54 mm) grid spaced terminals, which preclude the need for spreader pads, and its low profile make the J134 relay ideal for applications where high packaging density is important.

The Series J134D and J134DD have internal discrete silicon diodes for coil suppression and polarity reversal protection.

The sensitive J134 Centigrid® relay has a high resistance coil, thus requiring extremely low operating power (200 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay	Туре				Nom	inal Coil			
DPDT Non-Lat	Non-Latching Part No.		No.	Voltage	Resistance	P.U.V	D.O.V (Vdc)		Contact Load Rating
Diode C	Options			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
D = Internal did	ode for coil	- 2.2 M		5	100	3.5	0.12	2.5	Resistive: 1A/28Vdc
transient suppr	ression	Man	J134	6	200	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
DD = Internal o	liode for coil	0361- 1261	(M39016/41)	9	400	6.8	0.35	4.9	Lamp: 100mA/28Vdc
transient suppr	ression and		J134D (M39016/42)	12	800	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
polarity reversa	al protection	1/11		18	1600	13.5	0.59	10.0	
Vibration	Shock	10 I NI		26	3200	18.0	0.89	13.0	
30 q's	75 q's 6 msec,	a state		5	64	3.7	0.7	2.6	Resistive: 1A/28Vdc
to 3000 Hz	half-sine	M300		6	125	4.8	0.8	3.0	Inductive: 200mA/28Vdc (320mH)
Acceleration	Temperature	0361- 1261	J134DD (M39016/43)	9	400	8.0	0.9	4.5	Lamp: 100mA/28Vdc
	Operating &			12	800	11.0	1.0	5.8	Low Level: 10 to 50 uA/10 to 50 mV
50 a's	Storage:	INT I		18	1600	14.5	1.1	9.0	
	–65°C to +125°C	HI I M		26	3200	19.0	1.3	13.0	

Series J136C Electromechanical Relays

The sensitive J136C Centigrid® relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" (2.54 mm) grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The sensitive J136C Centigrid® relay has a high resistance coil, thus requiring extremely low operating power (200 mW, typical). The advantages of reduced heat dissipation and power supply demands are a plus. The sensitive Series J136C utilizes an internal silicon diode for coil suppression, a Zener diode to protect the MOSFET gate input, and an N-channel enhancement-mode MOSFET chip that enables direct relay interfacing with most microprocessor and IC logic families (CMOS, TTL and MOS).

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
 10 Million Cycle Life
- **Relay Type Nominal Coil Coil Current** DPDT Non-Latching Part No. P.U.V **Contact Load Rating** Voltage Operating (mA) (Vdc) (max. **CMOS** Feature (Vdc) Power (mW) Min Max Internal power MOSFET 5 43.0 56.0 250 4.0 Resistive: 1A/28Vdc driver, Zener diode gate protec-6 27.0 33.0 180 4.9 Inductive: 200mA/28Vdc (320mH) tion, and diode coil suppression Lamp: 100mA/28Vdc 9 17.8 26.4 203 7.3 J136C Vibration Shock (M28776/7) 12 11.3 177 180 98 Low Level: 10 to 50 uA/10 to 50 mV 30 g's 75 g's 6 msec, 18 8.4 13.8 203 14.6 to 3000 Hz half-sine 26 5.8 10.2 219 19.5 Acceleration **Temperature** Operating & Storage: 07 0 10 50 g's 0 ⁷@ @ [`] ⁷@ 0 0 2 O စို -65°C to +125°C δQ. ●² ିଡ୍ φ^2 ¥ 8 PIN 1: + SUPPLY PIN 9: - SUPPLY 50 0 ©⁵ 03 50 04 03 PIN 10: GATE 30 Ģ Schematics as viewed from terminals J134 J134D J134DD J136C

P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

Series J411 & J431 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed specifically for high-density PC board mounting, its small size and low coil power dissipation make the J411 relay one of the most versatile ultraminiature relays available.

The Series J411D and J411DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid J411T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

The sensitive J431 relay has a high resistance coil, thus requiring extremely low operating power (150 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus. The Series J431D and J431DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid J431T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay	Туре			Nominal Coil					
SPDT Non-Lat	ching	Part I	No.	Voltage	Resistance	P.U.V	D.O.V	(Vdc)	Contact Load Rating
Coil	Гуре			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
J411 = Standar	d Coil	States		5	63	3.7	0.15	2.4	Resistive: 1A/28Vdc
J431 = Sensitiv	e Coil	15- 2.5 D	J411	6	125	4.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
Diode C	ptions	111112	(M39016/7)	9	280	6.8	0.35	4.2	Lamp: 100mA/28Vdc
D = Internal dic	de for coil		J411D	12	500	9.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
ransient suppr	ession	1441	(M39016/23)	18	1130	13.5	0.58	8.4	
DD = Internal d	iode for coil	- 11		26	2000	18.0	0.89	10.4	
ransient suppr	ession and	a state		5	50	4.5	0.15	2.4	Resistive: 1A/28Vdc
olarity reversa	al protection	and the second second		6	98	5.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
Г = Internal tra	nsistor drive		J411DD	9	280	7.8	0.35	4.2	Lamp: 100mA/28Vdc
and coil transie	nt suppression		(M39016/24)	12	500	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
diode		(b k h l		18	1130	14.5	0.58	8.4	
Vibration	Shock			26	2000	19.0	0.89	10.4	
30 g's	75 g's 6 msec,	and the set		5	63	3.9	0.15	2.4	Resistive: 1A/28Vdc
to 3000 Hz	half-sine	and a second		6	125	5.2	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
cceleration	Temperature		J411T	9	280	7.8	0.35	4.2	Lamp: 100mA/28Vdc
			(11/20110/5)	12	500	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
	Operating &	1 P P P I		18	1130	14.5	0.58	8.4	
50 g's	Storage:			26	2000	19.0	0.89	10.4	
	–65°C to +125°C	Carling and		5	125	3.7	0.15	2.0	Resistive: 1A/28Vdc
		431 -5A	J431 (M39016/10)	6	255	4.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
		06461	(11000010,10)	9	630	6.8	0.35	4.2	Lamp: 100mA/28Vdc
	1411		J431D (M39016/25)	12	1025	9.0	0.41	5.6	Low Level: 10 to 50 uA/10 to 50 mV
	J431			18	2300	13.5	0.58	8.4	
		1 4 1		26	4000	18.0	0.89	10.4	
		C. State		5	100	4.5	0.15	2.4	Resistive: 1A/28Vdc
		-5A		0	200	5.5 7 0	0.18	2.8	
	U11D	83960	J431DD (M39016/26)	9	1005	1.0	0.35	4.2	Lamp. ToomA/28Vuc
	J431D		(12	1025	10.0	0.40	0.0	Low Level: 10 to 50 uA/10 to 50 mV
3 0 • • • 0 2				10	2300	14.5	0.00	0.4 10.4	
\bigcirc				20	4000	3.6	0.09	2.0	Posistivo: 14/29/do
		A THE A		6	255	J.0	0.15	2.0	Inductive: 200mA/28V/dc (320mH)
	a	-5A		q	630	7.8	0.10	4.2	L amp: 100mA/28Vdc
		83960	J4311 (M28776/4)	12	1025	10.0	0.41	5.6	L_{0} ow Level: 10 to 50 μ /10 to 50 mV
3 (○) 1 () 2	J49 IDD		(18	2300	14.5	0.58	8.4	
\smile				26	4000	19.0	0.89	10.4	
				20	1000	10.0	0.00	10.4	

P.U.V = Pick-Up Voltage

D.O.V = Drop-Out Voltage

J411T

J431T

Schematics as viewed from terminals

Series J412 & J432 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for lowlevel switching from dry circuit to 1 ampere. Designed specifically for high-density PC board mounting, its small size and low coil power dissipation make the J412 relay one of the most versatile ultraminiature relays available

The Series J412D and J412DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid J412T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

The sensitive J432 relay has a high resistance coil, thus requiring extremely low operating power (200 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus.

The Series J432D and J432DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid J432T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- · High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities 10 Million Cycle Life

Relay	Туре		Nominal Coil						
DPDT Non-Lat	ching	Part I	No.	Voltage	Resistance	PIIV	D.O.V	(Vdc)	Contact Load Rating
Coil	Гуре			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
J412 = Standar	d Coil	State of		5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
J432 = Sensitiv	ve Coil		J412	6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
Diode C	ptions	The second second	(M39016/9)	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
D = Internal dic	de for coil		J412D	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 uA
transient suppr	ession	I H H H I	(M39016/15)	18	880	13.5	0.59	10.0	
DD = Internal d	iode for coil			26	1560	18.0	0.89	13.0	
transient suppr	ession and	a contraction		5	39	3.9	0.6	2.8	Resistive: 1A/28Vdc
polarity reversa	al protection	122 8.50		6	78	5.2	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
T = Internal tra	nsistor drive	100021	J412DD	9	220	7.8	0.8	5.3	Lamp: 100mA/28Vdc
and coil transie	nt suppression	·	(M39016/20)	12	390	10.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 uA
diode		THAT		18	880	14.5	1.1	10.0	
Vibration	Shock	2011		26	1560	19.0	1.4	13.0	
30 a's	75 d's 6 msec	A La Lat		5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
to 3000 Hz	half-sine	1 2 2 2 2 2 3 D		6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
	Tomporaturo	TITLE	J412T	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
Acceleration	Temperature		(M28776/1)	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
	Operating &	14 4 41		18	880	13.5	0.59	10.0	
50 g's	Storage:			26	1560	18.0	0.89	13.0	
	-65°C to +125°C	and the second		5	100	3.5	0.14	2.5	Resistive: 1A/28Vdc
		43	43 J432 (M39016/11) 201 J432D	6	200	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
		0305		9	400	6.8	0.35	4.9	Lamp: 100mA/28Vdc
	J412			12	850	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
	J432		(M39016/16)	18	1600	13.5	0.59	10.0	
0004		11111		26	3300	18.0	0.89	13.0	
•		0000		5	64	3.7	0.7	2.6	Resistive: 1A/28Vdc
		-5A		6	125	4.8	0.8	3.0	Inductive: 200mA/28Vdc (320mH)
	J412D	0305	J432DD	9	400	8.0	0.9	4.5	Lamp: 100mA/28Vdc
	J432D		(1039016/21)	12	850	11.0	1.0	5.8	Low Level: 10 to 50 uA/10 to 50 mV
60 04				18	1600	14.5	1.1	9.0	
		11 1 1 1		26	3300	19.0	1.3	13.0	
	}	199 200 D		5	100	3.6	0.14	2.5	Resistive: 1A/28Vdc
	44200	-5A		6	200	4.8	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
	J412DD J432DD	0305	J432T	9	400	7.8	0.35	4.9	Lamp: 100mA/28Vdc
60-1-04		5520	(1012077013)	12	850	11.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
\sim				18	1600	14.5	0.59	10.0	
]			26	3300	19.0	0.89	13.0	
	Ž	Schematic	s as viewed f	rom termino	le				DIIV - Dick In Voltage
	J412T	Schemalic	a as viewed l		13				$\Gamma.0.V = \Gamma i c \kappa - 0 P Voltage$ D O V = Drop-Out Voltage

`**⊙**≁ **∢**(0)3 0 -04

J432T

Series J255 Electromechanical Relays

The Series J255 is an industry-standard, half-size, latching crystal can relay. It has a wide range of switching capabilities ranging from low level to 2 amps. The Series J255 latching relay configuration is double-pole double-throw (DPDT), so the relay offers excellent switching density and versatility. Half-Size Crystal Can Features:

- Low level to 2 amps
- Wide range of switching capabilities
- Smallest relay package capable of switching 2 amps
- Modernized assembly process
- Qualified to MIL-PRF39016/45
- · Lead-free (gold-plated wire lead only)

- All welded construction
- · Wire leads, gold-plated or solder-coated
- Matched seal for superior hermeticity
- Gold-plated contact assembly
- Modernized assembly process
- Advanced cleaning techniques
- 1 Million Cycle Life

Relay Type			Nomi	nal Coil		
DPDT Magnetic-Latching	Part No.	Voltage (Vdc)	Resistance (Ω)	Set & Res	et Voltage	Contact Load Rating
Vibration				Min.	Max.	
30G, 10-2500 Hz		5	45	1.0	3.8	Resistive: 2A/28Vdc
(Sinusoidal)	98.04	6	62	12	4.5	Inductive: 0.754/28//de (220mH)
Shock	1255	0	05	1.5	4.5	
100G, 6 msec half-sine	(M39016/45)	12	254	2.6	9.0	Intermediate Current: 0.1A/28Vdc
(Specified Pulse)		26	1000	5.2	18.0	Lamp: 0.16A/28Vdc
Temperature						Low Level: 10 to 50 uA/10 to 50 mV
Operating & Storage:		_				
–65°C to +125°C		5				

1255

Series J421 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, its small size and low coil power dissipation make the J421 relay one of the most versatile ultraminiature relays available.

SCHEMATIC

The Series J421D and J421DD utilize discrete silicon diodes for coil suppression and polarity reversal protection.

The Series J421 magnetic-latching relays are ideally suited for applications where coil power dissipation must be minimized. The relays can be operated with a short duration pulse. After the contacts have transferred, no external holding power is required. The magnetic-latching feature of the Series J421 provides a "memory" capability, since the relays will not reset upon removal of coil power.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay	Туре				Nominal C	oil	
SPDT Magneti	c-Latching	Part	No.	Voltage (Vdc)	Resistance (Ω)	Set & Reset Voltage (Vdc)	Contact Load Rating
Diode C	Options			5	61	3.5	Resistive: 1A/28Vdc
D = Internal die	ode for coil	No.C	1424	6	120	4.5	Inductive: 200mA/28Vdc (320mH)
transient suppr	ression	- 22		9	280	6.8	Lamp: 100mA/28Vdc
DD = Internal o	liode for coil	7. 8	(M39016/8)	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
transient suppr	ression and	Pp		18	1130	13.5	
polarity reversa	al protection			26	2000	18.0	
Vibration	Shock		14240	5	61	3.7	Resistive: 1A/28Vdc
30 g's	100 g's 6 msec,	285		6	120	4.5	Inductive: 200mA/28Vdc (320mH)
to 3000 Hz	half-sine	- 22		9	280	6.8	Lamp: 100mA/28Vdc
Acceleration	Temperature	12	(M39016/27)	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
	Operating &	VP		18	1130	13.5	
50 g's	Storage:			26	2000	18.0	
	–65°C to +125°C			5	48	4.5	Resistive: 1A/28Vdc
		No. Co		6	97	5.5	Inductive: 200mA/28Vdc (320mH)
*See Schematics on Page 27		. ??.	J421DD (M39016/28)	9	280	7.8	Lamp: 100mA/28Vdc
		The Party		12	500	10.0	Low Level: 10 to 50 uA/10 to 50 mV
		A PAR		18	1130	14.5	
				26	2000	19.0	
MILITARY QUALIFIED (JAN) RELAYS

Series J420 & J422 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, its small size and low coil power dissipation make the J420 & J422 relays some of the most versatile ultraminiature relays available.

The Series J420D/J422D and J420DD/J422DD utilize discrete silicon diodes for coil suppression and polarity reversal protection.

The Series J420/J422 magnetic-latching relays are ideally suited for applications where coil power dissipation must be minimized. The relays can be operated with a short duration pulse. After the contacts have transferred, no external holding power is required. The magnetic-latching feature of the Series J420/J422 relays provide a "memory" capability, since the relays will not reset upon removal of coil power.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay	Туре				Nominal C	oil	
DPDT Magnetic-Latching		Part	Part No.		Resistance	Set & Reset	Contact Load Rating
Grounding	g Options		1400	(Vac) E	(12)	2 F	Desistive: 14/20)/de
J420 = Commo	on	A La Lat	J420	Э	01	3.5	Resistive: TA/28vac
1422 – Individu	ual	127 8.51	(M39016/12)	6	120	4.5	Inductive: 200mA/28Vdc (320mH)
	Diode Options		J4ZZ	9	280	6.8	Lamp: 100mA/28Vdc
Diode C			J420D	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
D = Internal diode for coil transient suppression DD = Internal diode for coil		TITT	(M39016/29)	10	1120	12 5	
			J422D	10	1150	15.5	
			(M39016/29)	26	2000	18.0	
transient suppr	ession and	States		5	48	4.5	Resistive: 1A/28Vdc
polarity reversa	al protection	1 2 2 8 2 1 S	J420DD	6	97	5.5	Inductive: 200mA/28Vdc (320mH)
Vibration	Shock	A MARTINE ST	(M39016/30)	9	280	7.8	Lamp: 100mA/28Vdc
			142200	12	500	10.0	Low Level: 10 to 50 uA/10 to 50 mV
30 g s	iou g s 6 msec,	TEFUL	(M39016/30)	18	1130	14.5	
to 3000 Hz	half-sine		(26	2000	19.0	
Acceleration	Temperature			20	2000	13.0	



Operating & Storage:

-65°C to +125°C

50 g's

J420





Schematics Shown with Coil A Last Energized Schematics as viewed from terminals











HIGH-PERFORMANCE RELAYS

Series 412H, 422H & 432H Electromechanical Relays - High Temperature

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, these TO-5 relays are some of the most versatile ultraminiature relays available because of their small size and low coil power dissipation.

The H Series high-temperature TO-5 relays are designed for reliable operation in elevated ambient temperatures up to 200°C. Special material selection and processing provide assurance of freedom from contact contamination and mechanical malfunctioning that might otherwise be caused by ultra high ambient temperature conditions.

Typical applications:

• Oil exploration (down-hole) instrumentation

• High-Temperature industrial and process control instrumentation

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay Type				Nom	inal Coil			
412H = DPDT Non-Latching	Part No.		Voltage	Resistance	P.U.V	D.O.V (Vdc)		Contact Load Rating
432H = DPDT Non-Latching			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
422H = DPDT Magnetic-	10110		5	50	4.7	0.14	2.4	Resistive: 1A/28Vdc
Latching	412H-1-		6	98	5.9	0.18	3.4	Inductive: 200mA/28Vdc (320mH)
Coil Type	00071 36280	412H	9	220	9.0	0.35	5.1	Lamp: 100mA/28Vdc
412H = Standard Coil			12	390	11.9	0.41	6.8	Low Level: 10 to 50 uA/10 to 50 mV
422H = Standard Coil			18	880	17.8	0.59	10.2	
432H = Sensitive Coil			26	1560	24.0	0.89	13.5	
Vibration			5	100	4.7	0.14	2.4	Resistive: 1A/28Vdc
30 g's to 3000 Hz	4324		6	200	5.9	0.18	3.4	Inductive: 200mA/28Vdc (320mH)
Shock	08 08 36 48	4220	9	400	9.0	0.35	5.1	Lamp: 100mA/28Vdc
412H = 75 g/s 6 msec half-sine	4	4 3 2⊓	12	850	11.9	0.41	6.8	Low Level: 10 to 50 uA/10 to 50 mV
4201 = 75 g's 0 mscc, half sinc			18	1600	17.8	0.59	10.2	
			26	3300	24.0	0.89	13.5	
422H = 100 g/s								

Acceleration			Nominal C	oil	
50 g's	Part No.	Voltage	Resistance	Set & Reset	Contact Load Rating
Temperature		(vac)	(\$2)	voltage (vuc)	
Operating & Storage:	- and the	5	61	4.7	Resistive: 1A/28Vdc
Operating & Storage.	422H-5	6	120	5.9	Inductive: 200mA/28Vdc (320mH)
–65°C to +200°C	34328	9	280	9.0	Lamp: 100mA/28Vdc
	422H	12	500	11.9	Low Level: 10 to 50 uA/10 to 50 mV
	AUM	18	1130	17.8	
	111 U N -	26	2000	24.0	



412H 432H



Schematics as viewed from terminals

P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

HIGH-PERFORMANCE RELAYS

Series 412K & 422K Electromechanical Relays - High Shock

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, its small size and low coil power dissipation make the TO-5 relay one of the most versatile subminiature relays available.

The K Series high-shock TO-5 relays are designed to withstand shock levels up to 4000 g's. .5 msec duration. Special material selection and construction details provide assurance that critical elements of the relay structure and mechanism will not be permanently displaced or damaged as a result of extremely high g level shocks.

Typical applications:

- Commercial avionics aircraft control
- · Commercial aircraft control systems

2100 g's, 0.5 msec axial

750 g's, 0.5 msec side

plane, half-sine

planes, half-sine

Acceleration

50 g's Temperature Operating & Storage:

-65°C to +125°C

Transportation systems (rail/truck)

- All welded construction
- Unique uni-frame design providing high
- magnetic efficiency and mechanical rigidity · High force/mass ratio for resistance to
- shock and vibration Precious metal alloy contact material with
- gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay Type			Nom	inal Coil			
412K = DPDT Non-Latching	Part No.	Voltage	Resistance	P.U.V	D.O.V (Vdc)		Contact Load Rating
422K = DPDT Magnetic-		(Vdc) (Ω)		(Vdc) (max.)	min.	max.	
Latching		5	50	4.3	0.14	2.5	Resistive: 1A/28Vdc
Vibration	CEO EST	6	80	5.2	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
30 g's to 3000 Hz	05271	9	160	7.6	0.35	4.9	Lamp: 100mA/28Vdc
Shock	412K	12	300	10.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
412K = 75 g's 6 msec, half-sine		18	600	14.3	0.59	10.0	
4000 g's, 0.5 msec axial		26	1350	21.0	0.89	13.0	
plane, half-sine							
1000 d's 0.5 msec side			Nominal (Coil			
planes, half-sine	Part No.	Voltage	Resistance	Set & Re	set	Contact Load Rating	
422K = 100 g's 6 msec half sine		(Vdc)	(Ω)	Voltage (\	/dc)		
422R - 100 y 5 0 msec, nail-sine	122.24	5	61	3.5			Resistive: 1A/28Vdc

120

280

500

1130

2000

18.0

3.5	Resistive: 1A/28Vdc
4.5	Inductive: 200mA/28Vdc (320mH)
6.8	Lamp: 100mA/28Vdc
9.0	Low Level: 10 to 50 uA/10 to 50 mV
13.5	



6

9

12

18

26

422K



422K

Schematics as viewed from terminals P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

HIGH-PERFORMANCE RELAYS

Series 412V & 432V Electromechanical Relays - High Vibration

The 412V and 432V TO-5 relays, originally conceived and developed by Teledyne, have become the industry standards for low level switching from dry circuit to 1 ampere in high-vibration environments. Designed for high-density PC board mounting, these TO-5 relays are some of the most versatile ultraminiature relay available because of their small size and low coil power dissipation.

The V Series high-vibration relays are designed to withstand vibration levels of 250 to 380 g's at the frequencies noted, when tested on a resonant beam for 10 to 20 seconds, in the axis parallel to contact motion (x-axis), or 100 g's 10-2000 Hz for 20 minutes in the x-axis. A unique magnetic circuit prevents contact opening (chatter) in excess of 10 microseconds under vibration or shock conditions. Typical applications:

- Avionics aircraft control
- Aircraft control systems
- Transportation systems (rail/truck)

All welded construction

- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities
- 10 Million Cycle Life

Relay Type				Nom	inal Coil			
DPDT Non-Latching	Part No.		Voltage	Resistance	P.U.V	D.O.V (Vdc)		Contact Load Rating
Coil Type			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
412V = Standard Coil	01.10		5	50	4.6	0.14	2.3	Resistive: 1A/28Vdc
432V = Sensitive Coil	412V-12 07081		6	70	5.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
Diode Options	96640	412V	9	155	8.2	0.35	4.9	Lamp: 100mA/28Vdc
D = Internal diode for coil	1111	412DV	12	235	11.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
transient suppression	1111		18	610	16.5	0.59	10.0	
DD = Internal diode for coil	1141		26	1130	22.0	0.89	13.0	
transient suppression and	16,10	412DDV	5	33	4.6	0.6	2.8	Resistive: 1A/28Vdc
polarity reversal protection	412V-12 07081		6	44	5.5	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
Vibration	96646		9	125	8.2	0.8	5.3	Lamp: 100mA/28Vdc
250 g's at 140 ±5 Hz			12	215	11.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 mV
350 g's at 170 ±5 Hz			18	470	16.5	1.1	10.0	
380 g's at 200 ±5 Hz	1111		26	1050	22.0	1.4	13.0	
Shock	The second		5	80	4.6	0.14	2.5	Resistive: 1A/28Vdc
150 gia 11 maga half sing	-260		6	120	5.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
150 g s 11 msec, han-sine	52390	432V	9	240	8.2	0.35	4.9	Lamp: 100mA/28Vdc
Acceleration	TIT	432DV	12	480	11.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
50 g's	/////		18	950	16.5	0.59	10.0	
Temperature	77711		26	1900	22.0	0.89	13.0	
Operating & Storage:								



432V





Schematics as viewed from terminals

-65°C to +125°C

P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

SERIES SI800 / SI803



Bit Rate	Eye Height	Eye Width	Jitter _{P-P}
20 Gbps	191 mV	37 ps	10.22 ps

SERIES RF121





GRF121 @ 28Gbps





Reference @ 16Gbps





Reference @ 28Gbps

SERIES LB363



Normally Closed Path @ 16 Gbps



SERIES GLB363

AC BYPASS (Capacitor Path) @ 16 Gbps



Bit Rate	Eye Height	Eye Width	Jitter _{P-P}
16 Gbps	157 mV	49.4 ps	14.22 ps

Normally Closed Path @ 16 Gbps



SERIES SGLB363

AC BYPASS (Capacitor Path) @ 16 Gbps



Normally Closed Path @ 16 Gbps







SERIES SRF300/SRF303

SERIES RF300/RF303



Normally Open +130 mV 0 V R p-p L p-p -130 mV 0 ps 40 ps 80 ps 120 ps 160 ps Eye Width SNR Jitter_{P-P} Eye Height 72.8 mV 88.1 ps 4.31 8.00 ps



SERIES GRF300/GRF303

	Norr	nally Clos	ed		
					+130 mV
L (2-7)	€€₽₽				- 0 V
0 ps 4	Dps 80	0 ps	120 ps	160 ps	
Eye Height	Eye Wid	ith S	SNR	Jitter _{P-P}	
237.6 mV	90.08 p	os 1-	4.19	9.33 ps	



SERIES SGRF300/SGRF303



			4 1			i
0 ps 40		0 ps	80 ps	120 ps		160 ps
	Eye Height	Eye W	Vidth		INR	Jitter _{P-P}
	243.1 mV	90.29) ps	1	5.21	7.56 ps

 $\begin{array}{l} \textbf{PATTERN GENERATOR SETTINGS}\\ 10 \mbox{ Gbps Random Pulse Pattern Generator}\\ 2^{2i} - 1 \mbox{ PRBS signal}\\ \mbox{ PRBS output of $300mV_{\mu,\mu}$ (nominal)}\\ \mbox{ RF PCB effect (negligible) not removed from measurement}\\ \mbox{ Data shown is typical of both poles} \end{array}$

+130 mV

-130 mV

0 V

SERIES RF100





SERIES GRF100



Normally Open









SERIES GRF172



Normally Open 1 Open 1 Open ⊦130 mV 0 V -130 mV 0 Open 0 Open 0 ps 40 ps 80 ps 120 ps 160 ps Eye Height Eye Width SNR Jitter_{P-P} 268.2 mV 90.87 ps 21.62 7.56







Normally Open

SERIES RF311/RF331





SERIES RF341

SERIES GRF311/GRF331



Normally Open -130 mV 0 V Rp-p Lp-p -130 mV 0 ps 40 ps 80 ps 120 ps 160 ps Eye Height Eye Width SNR Jitter_{P-P} 271.5 mV 86.41 ps 21.35 8.89 ps



SERIES GRF341



Normally Closed

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SERIES GRF342



SERIES RF180



Normally Open +130 mV 1 Open 1 Open 0 V +---+---0 Open 0 Open -130 mV 0 ps 40 ps 80 ps 120 ps 160 ps Eye Height Eye Width SNR Jitter_{P-P} 235.8 mV 87.22 ps 12.75 10.22 ps





SERIES GRF180

SERIES RF424



SERIES GRF424



SERIES SGRF424









SERIES RF320/RF323



Normally Open +130 mV 0 V R p-p Lp-p -130 mV 0 ps 40 ps 80 ps 120 ps 160 ps Eye Height Eye Width SNR Jitter_{P-P} 268.2 mV 90.87 ps 21.62 7.56 ps

SERIES A150





SERIES GA150





SERIES A152



Thru Path +130 mV 0 V Lp-p R p-p -130 mV 0 ps 40 ps 80 ps 120 ps 160 ps Eye Height Eye Width SNR Jitter_{P-P} 124.5 mV 73.90 ps 5.23 22.22 ps

SERIES GA152



Thru Path +130 mV 0 V Lp-p Rp-p -130 mV 160 ps 40 ps 120 ps 0 ps 80 ps Jitter_{P-P} Eye Height Eye Width SNR 122.9 mV 76.21 ps 5.07 21.78 ps

RoHS and REACH CERTIFICATE OF COMPLIANCE

<u>RoHS</u>

It is hereby stated and certified that Teledyne Relays complies with the Restrictions on Hazardous Substances (RoHS) Directives to the extent herein:

Teledyne Relays does <u>not</u> use any of the Restricted Substances specified by the RoHS Directives

(listed below) as components in TO-5 and Centigrid[®] Electromechanical Relay products, nor are these substances employed during any electromechanical relay manufacturing process:

Lead Mercury Cadmium Hexavalent Chromium Polybrominated Biphenyls (PBB's) Polybrominated Diphenyl Ethers (PBDE's)

However, upon request from the Customer, relay leads may be coated with <u>solder</u>, which contains 60% tin and 40% lead.

<u>REACH</u>

It is hereby stated and certified that Teledyne Relays complies with the Registration Evaluation Authorization and Restriction of Chemicals (REACH) Directives to the extent stated herein:

Teledyne Relays is a manufacturer of articles. Teledyne Relays has taken the initiative to review the (155) substances that are under consideration for treatment as Substances of Very High Concern (SVHC) candidates. Teledyne Relays confirmed that our relays do not contain any of the listed

substances in concentration >0.1% weight per supplied article, substance or preparation weight.





For Additional Information please E-Mail us at: relays@teledyne.com

APPENDIX: TELEDYNE RELAYS PART NUMBERING SYSTEM



LoopBack Relays

General Note: Parts ordered without suffix may be supplied with Solder-Coated or Gold-Plated leads

¹ Parts ordered with Solder-Coated leads will have (Sn60/Pb40) ² Parts ordered with RoHS Solder-Coated leads will have (Sn99.3/Cu0.7)

³ Not Applicable to GRF relays

⁴ SMT=Surface Mount Technology

APPENDIX: TELEDYNE RELAYS PART NUMBERING SYSTEM



General Note: Parts ordered without suffix may be supplied with Solder-Coated or Gold-Plated leads. 1 Parts ordered with Solder-Coated leads will have (Sn60/Pb40) 2 Parts and with Solder-Coated leads will have (Sn60/Pb40)

2 Parts ordered with RoHS Solder-Coated leads will have (Sn99.3/Cu0.7)

TO-5 Package Relays (Through Hole)



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.270 (6.86)	412, 412D, 412DD, 412T
0.275 (6.99)	712, 712D, 712TN, RF300, RF300D, RF300DD, RF310, RF320, RF700
0.280 (7.11)	722, 722D, RF341, 420, 420D, 420DD, 421, 421D, 421DD, 422, 422D, 422DD
0.325 (8.26)	RF312, SI800, RF424, RF424D
0.375 (9.52)	432, 432D, 432DD, 432T
0.385 (9.76)	732, 732D, 732TN, RF303, RF303D, RF303DD, RF313, RF323
0.400 (10.16)	RF332, SI803

TERMINAL LOCATIONS AND PIN NUMBERING (REF. ONLY)

TO-5 Package Relays (Through Hole)



TERMINAL LOCATIONS AND PIN NUMBERING (REF. ONLY) (Viewed from Terminals) (Viewed from Terminals) .031 (.79) ±.003 (0.08) ±.010 (0.25) 200 (5.08) ±.010 (.25) DIA.

DIMENSIONS ARE SHOWN IN INCHES (MILLIMETERS)

"H" Dimension Max inches (mm)	Applicable Relays:				
0.280 (7.11)	RF341, ER421, ER421D, ER421DD, J421, J421D, J421DD				

CASE DETAIL .370 (9.40) DÍA.MÁX. .031(.79) ± .003(0.08) .335 (8.51) .200(5.08) DIA.MÁX. ±.010(.25) DIA. .035(.89) 💧 Ø Ť 6 ±.010(0.25) Ø 0 ර -0 н 0 0 ີ 6 ൕ 0 Ł Į WIRE LEAD: .75 (19.05) MIN. 36° ±3° TYP. PIN: .187 (4.75) ± . 010 (.25) Í ÍÍ 8 LEADS 5 LEADS (See Note 6) 45° ±3° TYP. .017(.43) +.002(.05) ±.001(.03) DIA. 411T 411, 411D, 411DD 431T 431, 431D, 431DD **RF311 RF331**

"H" Dimension Max inches (mm)	Applicable Relays:
0.270 (6.86)	411, 411D, 411DD, 411T
0.275 (6.99)	RF311
0.375 (9.52)	431, 431D, 431DD, 431T
0.385 (9.78)	RF331

TO-5 Package Relays (Surface Mount)



"H" Dimension Max inches (mm)	Applicable Relays:
0.315 (8.00)	GRF300
0.320 (8.13)	GRF342
0.365 (9.27)	GRF312, GRF424, GRF424D
0.425 (10.80)	GRF303
0.450 (11.43)	GRF332



"H" Dimension Max inches (mm)	Applicable Relays:
0.315 (8.00)	GRF311

TO-5 Package Relays (J-Lead Surface Mount)



"H" Dimension Max inches (mm)	Applicable Relays:
0.340 (8.64)	SGRF300
0.390 (9.91)	SGRF312, SGRF424, SGRF424D
0.440 (11.18)	SGRF303
0.465 (11.81)	SGRF332



"H" Dimension Max inches (mm)	Applicable Relays:
0.340 (8.64)	SRF300
0.345 (8.76)	S422, S422D, S422DD
0.460 (11.18)	SRF303

Centigrid® Package Relays (Through Hole)





"H" Dimension Max inches (mm)	Applicable Relay Series:
0.275 (6.99)	114, 114D, 114DD
0.280 (7.11)	172, 172D
0.290 (7.37)	RF100
0.375 (9.53)	134, 134D, 134DD
0.395 (10.03)	RF103

Centigrid® Package Relays (Surface Mount)



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.330 (8.38)	GRF100, GRF172, GRF172D
0.435 (11.05)	GRF103

Centigrid® Package Relays (J-Lead Surface Mount)



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.355 (9.02)	SGRF100
0.460 (11.68)	SGRF103



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.360 (9.14)	S114, S114D, S114DD
0.370 (9.40)	S172, S172D
0.460 (11.68)	S134, S134D, S134DD

Extended Centigrid® Package Relays (RF121 - Through Hole)



"H	" Dimension Max inches (mm)	Applicable Relay Series:
	0.345 (8.77)	RF121

Extended Centigrid® Package Relays (GRF121 - Surface Mount)



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.385 (9.78)	GRF121

Extended Centigrid® Package Relays (Through Hole)



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.295 (7.49)	122C
0.300 (7.62)	RF180



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.275 (6.99)	116C
0.375 (9.53)	136C

Extended Centigrid® Package Relays (Through Hole)



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.280 (7.11)	A150
0.295 (7.49)	A152

Extended Centigrid® Package Relays (Surface Mount)



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.335 (8.51)	GA152

LoopBack Package Relays (Through Hole)



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.375 (9.52)	LB363

LoopBack Package Relays (Surface Mount)



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.415 (10.54)	GLB363

LoopBack Package Relays (J-Lead Surface Mount)



"H" Dimension Max inches (mm)	Applicable Relay Series:
0.443 (11.25)	SGLB363

Half-Size Crystal Can Package Relays (Through Hole)





MEASUREMENTS IN INCHES (MILLIMETERS)



"H" Dimension Max inches (mm)	Applicable Relay Series:	
0.410 (10.41)	255, 257, RF255, RF257	

Handling Guidelines for TO-5 and Centigrid® Relays

1) Do not drop, throw or in any way mishandle individual relays, cartons containing relay packs, or individual relay packs.

2) Store unused relays in a humidity controlled, shock and vibration-free environment. Storage temperature range limits -65°C to + 125°C, however, when possible, relays should be stored in a 25°C environment.

3) Observe normal good practice in the handling and storage of any relay packs marked as static sensitive.

4) When removing relays from packaging, do so with care. If removing relays from Styrofoam packaging, remove relays carefully as pouring them from the packaging may cause damage to the relay. If removing from bulk packaging, gently pour the relays from the container, taking care to not allow the relays to drop from the container onto the new surface, to prevent unnecessary shock. Do not allow relays to fall onto the floor.

5) When transferring relays to the production area after unpacking, do not drop, throw, or mishandle the relays in any way. When removing relays from the container, pouring is acceptable but again should be done gently and in a way as to not allow the relays to drop.

6) Attached relay spreader pads and insulating pads should not be removed from the relays.

7) Relays should not be exposed to any process or environment that exceeds any limits within this guide or any published specification that applies to the relay.

8) Relays are hermetically sealed. Damaged to the casing or glass-to-metal seals will compromise the relays' performance and reliability.

9) Never subject relays to ultrasonic cleaning environments.

10) Unless otherwise specified, do not subject relays to solder reflow temperatures above 270°C, 1 minute maximum.

11) Do not stack heavy object directly onto relays.

12) Excessive handling of relay leads with bare hands, or exposure of the relay leads with other contaminating sources can compromise their solderability.

13) Avoid exceeding 1-pound pull strength of the terminals.

14) Avoid subjecting magnetic latching relays to large magnetic fields. Do not handle magnetic latching relays with magnetic holding tools.

15) Avoid bending the flange, the base of the relays or bending/forming the leads in a manner which may result in deformation of the flange or base of the relays. Any such deformation, or handling, which results in visible deformations or dents to any part of the relays (including the cover) may compromise the precisely assembled internal parts of the relays, causing degradation of performance or potential permanent damage and may void the warranty.

APPENDIX: Spacer Pads

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
		ER412, ER412D, ER412DD	.295 (7.49)
Ø.150 [3.81] (REF)		712, 712D, 712TN, RF300, RF310, RF320 RF700, RF703	.300 (7.62)
		ER420, ER420D, ER420DD, 421, ER421D, ER421DD, ER422, ER422D, ER422DD, 722, 722D, RF341	.305 (7.75)
		ER431T, ER432T, ER432, ER432D, ER432DD	.400 (10.16)
		732, 732D, 732TN, RF303, RF313, RF323	.410 (10.41)
"M4" Pad for TO-5		RF312, RF332 SI800, SI803	.350 (8.89)
_T		ER411, ER411D, ER411DD, ER411T	.295 (7.49)
		ER431, ER431D, ER431DD	.400 (10.16)
$\bigcirc \bigcirc \bigcirc \bigcirc$		RF311	.300 (7.62)
"M4" Pad for TO-5		RF331	.410 (10.41)
_		172, 172D	.305 (7.75)
	Dim H MAX	ER114, ER114D, ER114DD, J114, J114D, J114DD	.300 (7.62)
		ER134, ER134D, ER134DD, J134, J134D, J134DD	.400 (10.16)
		RF100	.315 (8.00)
"M4" Pad for Centigrid®		RF103	.420 (10.67)
.156 [3.96] (REF)		122C, A152	.320 (8.13)
	Dim H MAX	ER116C, J116C	.300 (7.62)
.256 [6.5] (REF) 0 0 0		ER136C, J136C	.400 (10.16)
		RF180	.325 (8.25)
"M9" Pad for Centigrid®		A150	.305 (7.75)
Notes: 1. Spacer pad material: Polvester film.			

 To specify an "M4" or "M9" spacer pad, refer to the mounting variants portion of the part numbering example in the applicable datasheet.

- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is \pm .010" (.25 mm).
- 5. Add 10 m $\!\Omega$ to the contact resistance shown in the datasheet.
- 6. Add 0.01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.

APPENDIX: Spreader Pads

Pad designation and bottom view dimensions	esignation and Height For use with the following:		Dim. H Max.
370 [9.4] MAX SQ		ER411T, J411T, ER412, ER412D ER412DD, J412, J412D, J412DD ER412T, J412T	.388 (9.86)
	Dim H	712, 712D, 712TN	.393 (9.99)
	MAX 014 [0.36] (REF)	ER431T, J431T, ER432, ER432D ER432DD, J432, J432D, J432DD ER432T, J432T	.493 (12.52)
		732, 732D, 732TN	.503 (12.78)
"M" Pad <u>5</u> / <u>6</u> /	.370 [9.4] MIN	ER420, J420, ER420D, J420D ER420DD, J420DD, ER421, J421 ER421D, J421D, ER421DD J422D, ER422DD, J422DD, 722	.398 (10.11)
390 [9.91] SQ100 [2.54]	<u>+</u>	ER411T ER412, ER412D, ER412DD J412, J412D, J412DD	.441 (11.20)
		712, 712D	.451 (11.46)
.150 .300 [7.62] (2.54] (3.81] (3.81] (3.81]		ER421, ER421D, ER421DD 722, 732D	.451 (11.46)
		ER431T ER432, ER432D, ER432DD	.546 (13.87)
"M2" Pad <u>7</u> / <u>8</u> /		732, 732D	.556 (14.12)
	<u>† </u>	ER411, ER411D, ER411DD, ER411TX ER412X, ER412DX, ER412DDX ER412TX	.388 (9.86)
		712X, 712DX, 712TNX	.393 (9.99)
1.150 (3.81) (7.62)	014 (REF)	ER420X, ER420DX, ER420DDX ER421X, ER421DX, ER421DDX ER422X, ER422DX ER422DDX, 722X, 722DDX	.398 (10.11)
	(2.54) 370 200 MIN (5.08) Image: Constraint of the second s	ER431, ER431D, ER431DD ER431TX ER432X, ER432DX, ER432DDX ER432TX	.493 (12.52)
"M3" Pad <u>5</u> / <u>6</u> / <u>9</u> /	U U U	732X, 732DX, 732TNX	.503 (12.78)

Notes:

- 1. Spreader pad material: Diallyl Phthalate.
- 2. To specify an "M", "M2" or "M3" spreader pad, refer to the mounting variants portion of the part number example in the applicable datasheet.
- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is ± .010" (0.25 mm).
- <u>5</u>/. Add 25 m Ω to the contact resistance shown in the datasheet.
- 6/. Add .01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.
- $\underline{7}$ /. Add 50 m Ω to the contact resistance shown in the datasheet.
- 8/. Add 0.025 oz (0.71 g) to the weight of the relay assembly shown in the datasheet.
- 9/. M3 pad to be used only when the relay has a center pin (e.g. ER411M3-12A, 722XM3-26.)

APPENDIX: Ground Pin Positions



ER411T, ER412, ER412T, ER420, ER421, ER422,

ER431T, ER432, ER432T, 712, 712TN, 400H, 400K, 400V, RF300, RF303, RF341, RF312, RF332, RF310, RF313, RF320, RF323, SI800, SI803, RF700, RF703

"Z" POSITION Ø.200 [Ø5.08] € 45°±3° ("Y" POSITION

TO-5 Relays: ER411, ER431, RF311, RF331



Centigrid® Relays: RF180, ER116C, 122C, ER136C



Centigrid® Relays: RF100, RF103, ER114, ER134, 172



Loopback Relays: LB363

- Indicates ground pin position
- Indicates glass insulated lead position
- Indicates ground pin or lead position depending on relay type
- NOTES
- 1. Terminal views shown
- 2. Dimensions are in inches (mm)
- 3. Tolerances: \pm .010 (\pm .25) unless otherwise specified
- 4. Ground pin positions are within .015 (0.38) dia. of true position
- 5. Ground pin head dia., 0.035 (0.89) ref: height 0.010 (0.25) ref.
- 6. Lead dia. 0.017 (0.43) nom.

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APPENDIX: Teledyne Relays T²R Program

Teledyne Relays' *T*[#] program was developed to provide the JAN relay user an alternate means of specifying and procuring established reliability relays. The form, fit and function of a *T*[#] relay is the same as that of its JAN counterpart. *T*[#] program requirements differ in certain regimens/tests found in both MIL-PRF-28776 and MIL-PRF-39016 that add cost but no value to the relay.

This program parallels the military specifications in most aspects. The components that make up such a program are intricate and varied. Furthermore, there are additional options of high value for design, manufacturability and operation of high reliability assemblies. The following page presents a table that compares the 100% screening performed on JAN relays and *Till* relays prior to shipment.

Other significant highlights of the *T*[#] program include:

- Two unique screening levels
- The ability to define lead finish
- · Spacer pad options which may not be available in military specifications
- · Ground pin options which may not be available in military specifications
- Reduced lead time
- Reduced cost

The program is fully defined for both general product requirements and detailed product requirements in the following Teledyne Relays specifications:

TR-R-1 TR-STD-1 TR-STD-2 TR-ERL-1 TR-R-1/XXX TR Supplement

Copies of these documents are available from Teledyne Relays. We suggest that users check with Teledyne Relays from time to time to assure that they have the latest issue.

Can't Find What You Need?

Check out our full line of relays and switches. Order literature online at http://www.teledynerelays.com/lit-request.asp



APPENDIX: Teledyne Relays T²R Program

	Screening Levels				
INSPECTION	TE A Level 1.5%/10K Cycles	TE B Level .75%/10K Cycles	JAN L Level 3%/10K Cycles	JAN M Level 1%/10K Cycles	
Subgroup 1					
Screening, Internal Moisture AQL1	\checkmark	\checkmark	\checkmark	\checkmark	
Vibration (Sinusoidal) AQL ¹			\checkmark		
Vibration (Sinusoidal) 100%		\checkmark		\checkmark	
Screening, Burn-In (Hybrids only)			\checkmark	\checkmark	
Screening, Run-In (Room Temperature)	\checkmark				
Screening, Run-In (+125°C and –65°C)		✓	\checkmark	✓	
Subgroup 2					
Coil Resistance or Coil Current	\checkmark	\checkmark	\checkmark	\checkmark	
Insulation Resistance	\checkmark	✓	\checkmark	✓	
Dielectric Withstanding Voltage	\checkmark	✓	\checkmark	\checkmark	
Static Contact Resistance	~	✓	\checkmark	✓	
Pickup and Dropout or Set and Reset Voltage	\checkmark	✓	\checkmark	✓	
Operate and Release or Set and Reset Time	\checkmark	✓	\checkmark	✓	
Hold Voltage			✓	✓	
Turn-On and Turn-Off Time (Hybrids only)	\checkmark	✓	\checkmark	✓	
Contact Bounce Time	\checkmark		\checkmark		
Contact Stabilization Time		✓		✓	
Turn-On Current (T Hybrids only)	\checkmark	✓	\checkmark	✓	
Turn-On Voltage (C Hybrids only)	~	✓	√	√	
Turn-Off Voltage (Hybrids only)	~	✓	√	✓	
Coil Transient Suppression (D, DD and Hybrids only)	\checkmark	✓	\checkmark	\checkmark	
Diode Blocking Integrity (DD only)	~	✓	\checkmark	✓	
Zener Voltage (C Hybrid only)	\checkmark	✓	\checkmark	✓	
Neutral Screen (Latching Relays only)	✓	✓	\checkmark	✓	
Break Before Make Verification			\checkmark	✓	
Contact Simultaneity			\checkmark	✓	
Subgroup 3					
Solderability 2 Samples per Daily Solder- ability Inspection Lot	\checkmark	✓	\checkmark	✓	
Leak Test	\checkmark	\checkmark	\checkmark	\checkmark	
External Visual and Mechanical Inspection 2/Lot for Dimension and Weight Check	\checkmark	\checkmark	\checkmark	\checkmark	

1 AQL = Acceptable Quality Level
Teledyne Relays: Because in deep space there is no acceptable failure rate

Teledyne Relays has a long history of supplying High Reliability relays for use in space bound vehicles. From the earliest deep space probes, such as Voyager I, now nearing 21 billion miles out in space, to the next generation of probes scheduled for the future, Teledyne Relays continues to be the preeminent supplier of Hi-Reliability relays to the space market.

Teledyne Relays Hi-Reliability Specification: TR-HIREL-1

- Eliminates the need for customers to develop and maintain specifications.
- Manufacturing and Quality Assurance requirements are fully defined and documented.
- Meets the general requirements of both ESA/ SCC and NASA/GSFC documents.
- Offers options for 100% Group A screening
- Offers options for 3 levels of Lot Acceptance Testing (LAT).

Teledyne Screening Document 0-40-837

NASA approved screening regimen based on NASA/GSFC S-311-P.754



RELAY TYPES

TO-5 Magnetic-Latching Relays TO-5 Non-Latching Relays TO-5 Magnetic-Latching, High-Shock Relays TO-5 Non-Latching, High-Shock Relays TO-5 Non-Latching, High-Vibration Relays

HI-REL SCREENING CAPABILITIES

100% Open Electrical Inspection 100% Precap Inspection Fully Automated Small Particle Inspection (Millipore Clean) Asynchronous Miss Test **Coil Continuity** Sine Vibration Random Vibration High/Low Run In (Miss Test) -65 °C ± 125 °C Radiographic Inspection Mechanical Shock Test Thermal Shock Test Acceleration Radiographic Inspection (X-ray) Mechanical Shock Test Thermal Shock Test Acceleration Load Banks for a Variety of Life Test Load Serialized Printed Electrical Data Continuous Life Testing Environmental Testing Vertical Integration

For information or answers to your questions, please visit our website.



Teledyne Relays offers electromechanical relays for various markets?

RF RELAYS

- Signal Integrity up to 40Gbps
- DC 16GHz
- Surface-Mount
- DPDT, SPDT, 4PST and Loopback Relays





MILITARY GRADE RELAYS

- Built and tested to meet MIL-PRF-39016
- Built and tested to meet MIL-PRF-28776
- Built-in Diodes, Transistor Driver and **CMOS**
- Low Power coils

TELEDYNE ESTABLISHED RELIABILITY RELAYS

- Fully defined product requirements and screening levels
- Spacer/Spreader pad options not allowed by military specifications
- Reduced lead time and cost vs Military Grade

HIGH PERFORMANCE RELAYS

- -65°C to +200°C
- Shock up to 4,000 g's
- Vibration up to 380 g's
- Non-Latching & Magnetic-Latching

COMMERCIAL RELAYS

- Standard electrical tests at 25°C
- "Low cost" switching solutions
- · Surface-Mount
- Short lead times















Teledyne Coax Switches offers coaxial switches for ATE, Radar, Amplifier Switching, Etc.?

SPDT SWITCHES

- DC 40GHz, Internal 50 Ω Termination
- SMA, mini-SMB, TNC & N Connectors
- 5 Million Cycles
- High Power & Low PIM
- Failsafe & Latching

TRANSFER SWITCHES

- DC 18GHz
- SMA, TNC & N Connectors
- 5 Million Cycles
- High Power
- Failsafe & Latching

MULTI-THROW SWITCHES

- DC 40 GHz, Internal 50 Ω Termination
- SMA, mini-SMB, TNC & N Connectors
- SP3T SP10T
- 5 Million Cycles
- Normally Open & Latching

LOW PIM SWITCHES

- DC 3 GHz
- SMA, N and 7/16 D Connectors
- SPDT, Transfer and Multi-Throw
- Failsafe & Latching

SPECIALTY SWITCHES

- DC 40GHz
- 3-State Attenuated Switch
- Radiation Shielding
- Switch Blocks
- Redundant Diode Configuration



















Teledyne Relays offers Commercial/Industrial Solid State Relays?

SINGLE PHASE AC SOLID STATE RELAYS

- Up to 690Vac, 125A
- Input & Output Protection
- Chassis, DIN Rail and PCB Mount
- Zero-Cross & Random Switching
- Touch-Proof Covers



• Up to 600Vac, 50A

- Output Protection
- Chassis and DIN Rail
- · Zero-Cross & Random Switching
- Touch-Proof Covers



- Up to 600Vac, 75A
- Output Protection
- Chassis and DIN Rail
- · Zero-Cross & Random Switching
- DC & AC Control

DC SOLID STATE RELAYS

- Up to 1400Vdc, 100A
- Output Protection
- · Chassis, DIN Rail and PCB Mount
- IGBT and MOSFET
- Touch-Proof Covers



- Up to 26kW, 480Vac
- Star & Delta Configurations
- DIN Rail
- Output Protection
- Built-in Diagnostics and Self Test











Teledyne Relays offers Military Solid State Relays?

DC SOLID STATE RELAYS

- Meet MIL-PRF-28750
- Tested Per MIL-STD-704
- Silicon Carbide MOSFET
- Up to 250Vdc, 1A
- Chassis and PCB Mount
- Short-Circuit Protection
- Plastic and Hermetically Sealed

BI-DIRECTIONAL/AC SOLID STATE RELAYS

- Meet MIL-PRF-28750
- Tested Per MIL-STD-704
- Up to 250Vac, 25A
- Chassis and PCB Mount
- Short-Circuit Protection
- Plastic and Hermetically Sealed

COMMERCIAL, LOW POWER, I/O MODULES

- Up to 250Vac, 10A
- Short-Circuit Protection
- Chassis and PCB Mount
- Zero-Cross & Random Switching
- Low Off-State Leakage Current

SILICON CARBIDE TECHNOLOGY

- Up to 270Vdc, 20 A
- Meet MIL-PRF-28750
- Tested Per MIL-STD-704
- Low ON resistance
- Low Profile Hermetic Package





















Teledyne Coax Switches offers coaxial switch matrices for ATE, Radar, Filter Switching, Airborne Surveillance Systems, Etc.?

MINI MATRICES

- Remote Control via USB and/or Ethernet
- GUI controllable
- Accepts ASCII code
- Available in 18, 26.5 and 40 GHz
- SPDT, Transfer and Multi-throw configurations

MULTIPLEXOR/FANOUT SWITCH MATRICES

- Up to 1x1024 Switch Matrix
- SMA, mini-SMB, TNC & N Connectors
- Failsafe, Latching or Normally Open Configurations
- Switching Systems for 50 Ω & 75 Ω applications



MIMO/BLOCKING AND MIMO SINGLE CONNECTION SWITCH MATRICES

- Up to 1x1024 Switch Matrix
- SMA, mini-SMB, TNC & N Connectors
- RS-232, TTL, USB, GPIB, TTL, Ethernet Control
- 1 Million Cycles
- Failsafe & Latching

CUSTOMIZED SWITCH MATRICES

- EMI/RFI
- Transient Suppression
- Ballistic Shock Fatigue
- Crash Load
- Altitude



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Teledyne Relays offers Space Qualified Switches?

SPACE MARKET SEGMENTS SERVED

- Deep-Space Probes
- Manned Programs
- Communications Satellites
- Launch Vehicles
- Earth Observatory / Weather Satellites
- Commercial / Military Satellites





CAPABILITIES

- Logistic Infrastructure
- Chemical Analysis Lab
- Scanning Electro Microscope
- In-house Plating Shop
- Enviroment Test Lab
- Field Technical Support

ELECTROMECHANICAL RELAY SPECIFICATIONS

- MIL-PRF-39016
- MIL-PRF-28776
- NASA/GSFC S-311-P-754
- NASA EEE-INST-002
- ESA/SCC 3601 & 3602













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